

Matière condensée topologique



Mark Oliver Goerbig



Comprendre le monde,
construire l'avenir



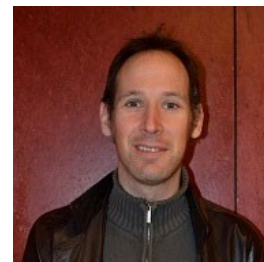
**Sergueï Tchoumakov, Xin Lu (PhD thesis)
Dibya Kanti Mukherjee (post-doc)**

Collaborators: D. Carpentier (ENS-Lyon)



Journée PhOM-P2I, Saclay, 20/06/2019

Théorie de la matière topologique au LPS



- *Isolants topologiques*
- *Graphène et semi-conducteurs bi-dimensionnels*
- *Semi-métaux de Dirac et de Weyl tri-dimensionnels*
- *Supraconductivité topologique*
- *Effets Hall quantiques*

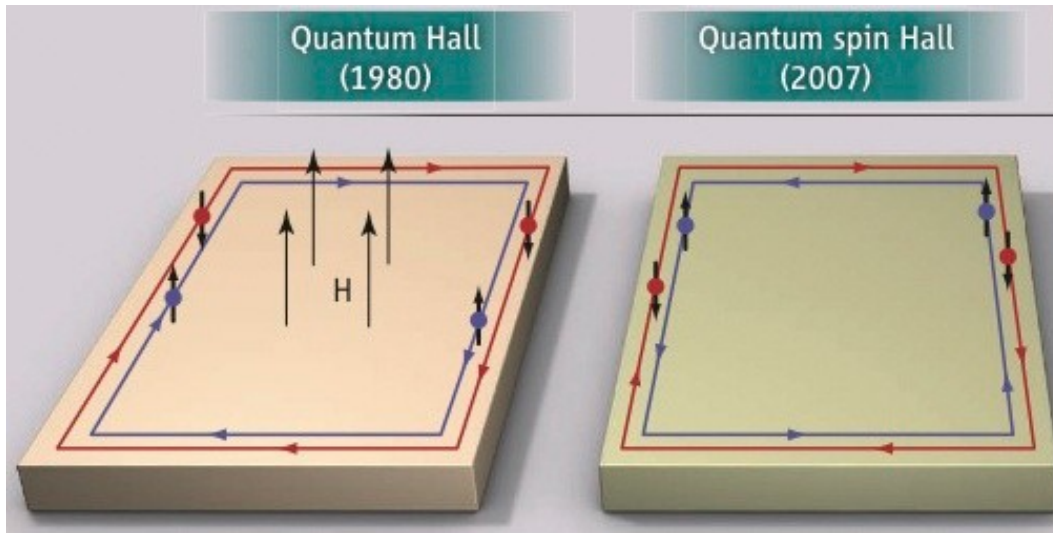
Outline

- Introduction to Berry curvature and bulk-edge correspondence
- Dirac fermions and “half Chern numbers”
- 2D Model of a smooth interface – from chiral to massive *relativistic* interface states
- Weyl semimetals with smooth surfaces

Outline

- Introduction to Berry curvature and bulk-edge correspondence
- Dirac fermions and “half Chern numbers”
- 2D Model of a smooth interface – from chiral to massive *relativistic* interface states
- Weyl semimetals with smooth surfaces

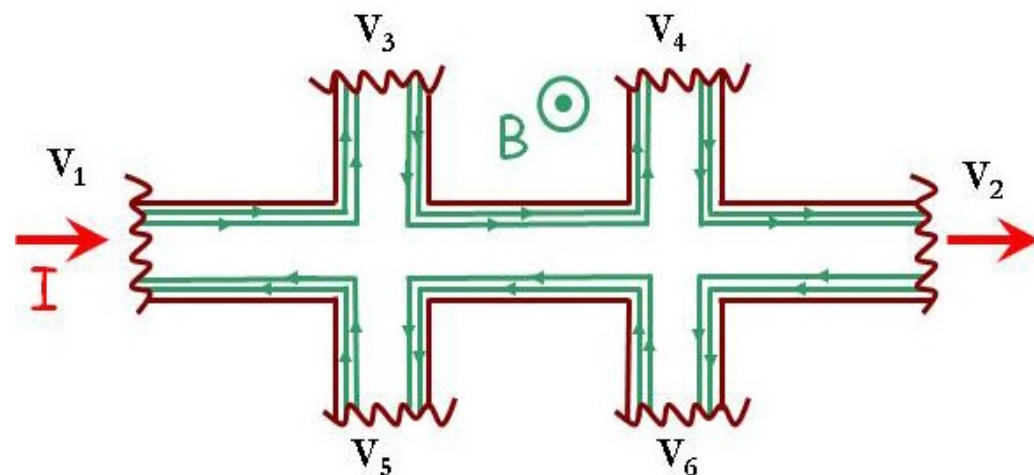
Topological insulators (1980 → 2007)



Science, 766, **318** (2007),
Würzburg group

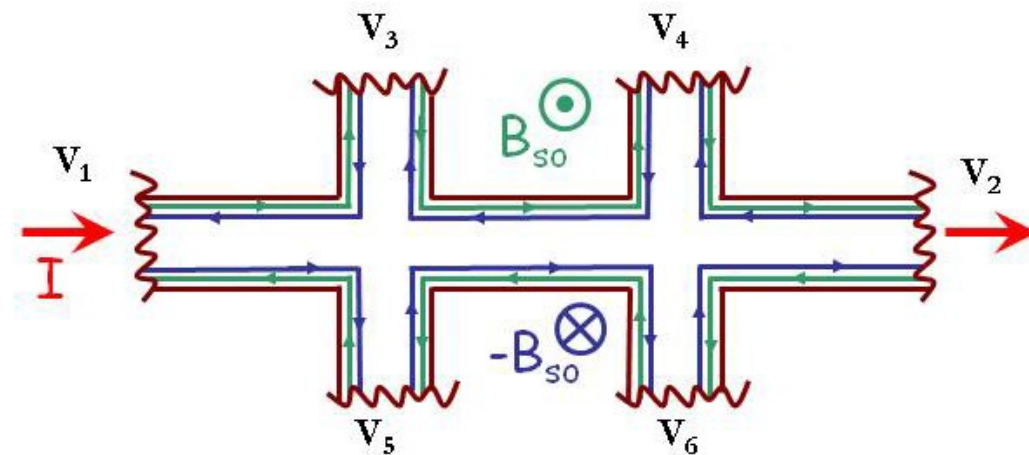
**Topological insulator =
Bulk insulator +
Conducting edges (surfaces)**

Quantum Hall effect



all states move in the same
direction
(chiral edge states)

Quantum spin Hall effect



spin up and spin down states
move in opposite directions
(helical edge states)

Information beyond the spectrum

Wave functions (\rightarrow “spin”):

$$H = \begin{pmatrix} \Delta & f(\mathbf{k})^* \\ f(\mathbf{k}) & -\Delta \end{pmatrix}$$

$$\psi_{+, \mathbf{k}} = \begin{pmatrix} \cos \frac{\theta}{2} \\ e^{i\phi} \sin \frac{\theta}{2} \end{pmatrix} \quad \psi_{-, \mathbf{k}} = \begin{pmatrix} -\sin \frac{\theta}{2} \\ e^{i\phi} \cos \frac{\theta}{2} \end{pmatrix}$$

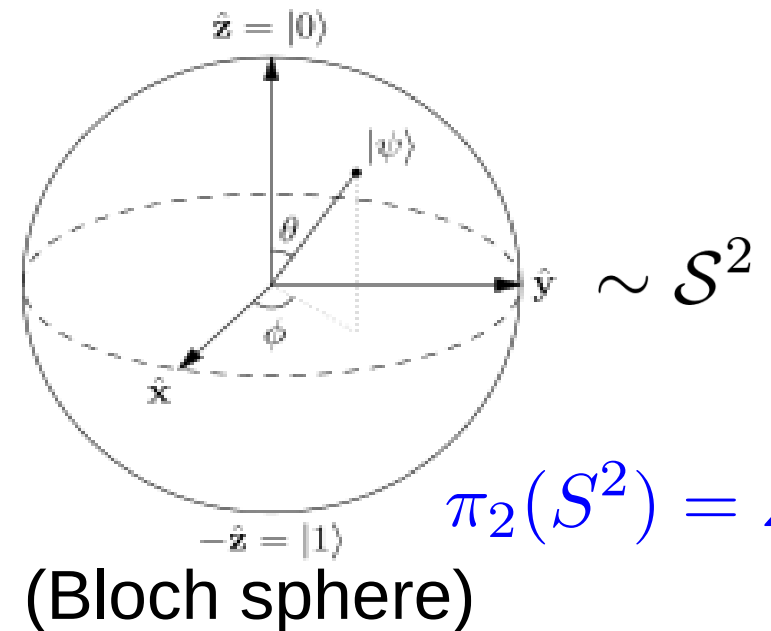
with $\cos \theta = \frac{\Delta}{\sqrt{\Delta^2 + |f(\mathbf{k})|^2}}$ and $\tan \phi = \frac{\text{Im} f(\mathbf{k})}{\text{Re} f(\mathbf{k})}$

\rightarrow *topological invariant:*
number of Bloch sphere coverings

$$\psi_{\pm} : \quad \mathbf{k} \in \mathcal{T}^2 \quad \rightarrow$$

(Brillouin zone)

\rightarrow *gap must change sign to have* $n \neq 0$
(“gap inversion”) !!



Mathematical formulation (→ Berry)

Geometric (Berry) phase (\sim magnetic flux):

$$\gamma_C = \int_C d\mathbf{k} \cdot \mathcal{A}_\lambda(\mathbf{k}) \quad \psi_\lambda(t) = e^{-iEt/\hbar} e^{-i\gamma_C} \psi_{\lambda,\mathbf{k}}(t)$$

$\lambda = \pm$: band index

Berry connection (\sim vector potential):

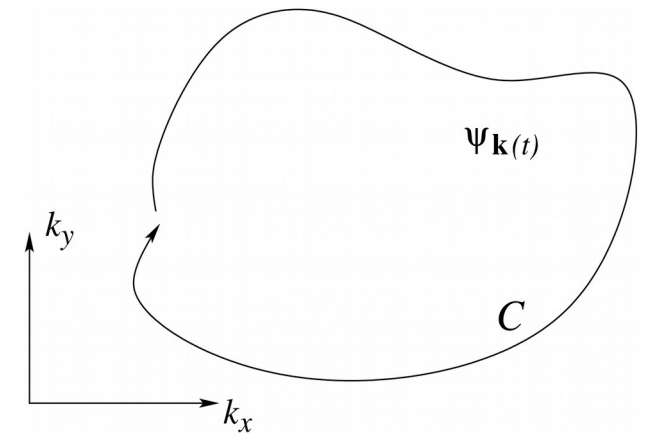
$$\mathcal{A}_\lambda(\mathbf{k}) = i\psi_{\lambda,\mathbf{k}}^\dagger \nabla_{\mathbf{k}} \psi_{\lambda,\mathbf{k}}$$

Berry curvature (\sim magnetic field):

$$\mathcal{B}_{\lambda,\mathbf{k}} = \nabla_{\mathbf{k}} \times \mathcal{A}_\lambda(\mathbf{k})$$

Chern number (topological invariant):

$$C_\lambda = \frac{1}{2\pi} \int_{BZ} d^2k \mathcal{B}_{\lambda,\mathbf{k}} \quad \text{integer}$$

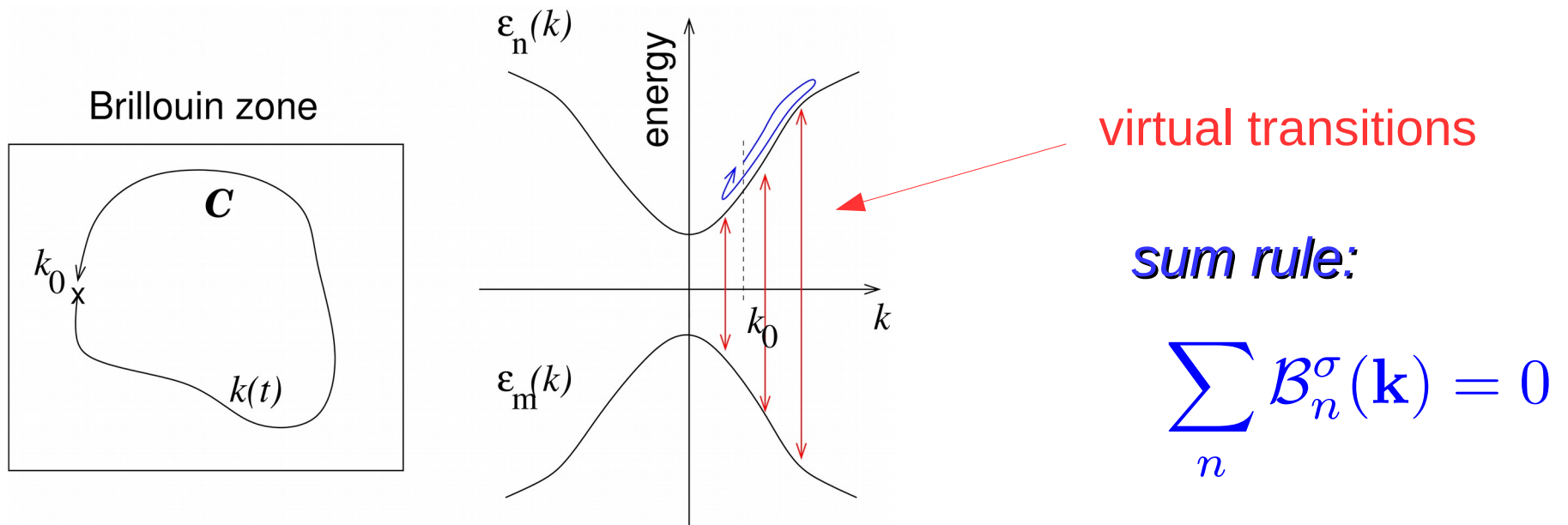


Berry curvature – some properties

$$\mathcal{B}_n^\sigma(\mathbf{k}) = i\epsilon^{\sigma\mu\nu} \sum_{m \neq n} \frac{\langle u_n | \partial_{k_\mu} H(\mathbf{k}) | u_m \rangle \langle u_m | \partial_{k_\nu} H(\mathbf{k}) | u_n \rangle}{[E_n(\mathbf{k}) - E_m(\mathbf{k})]^2}$$

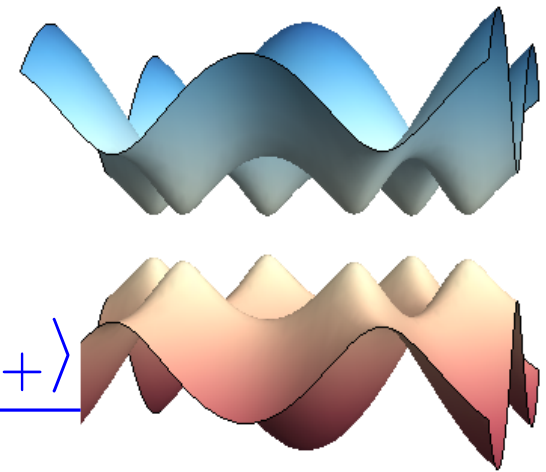
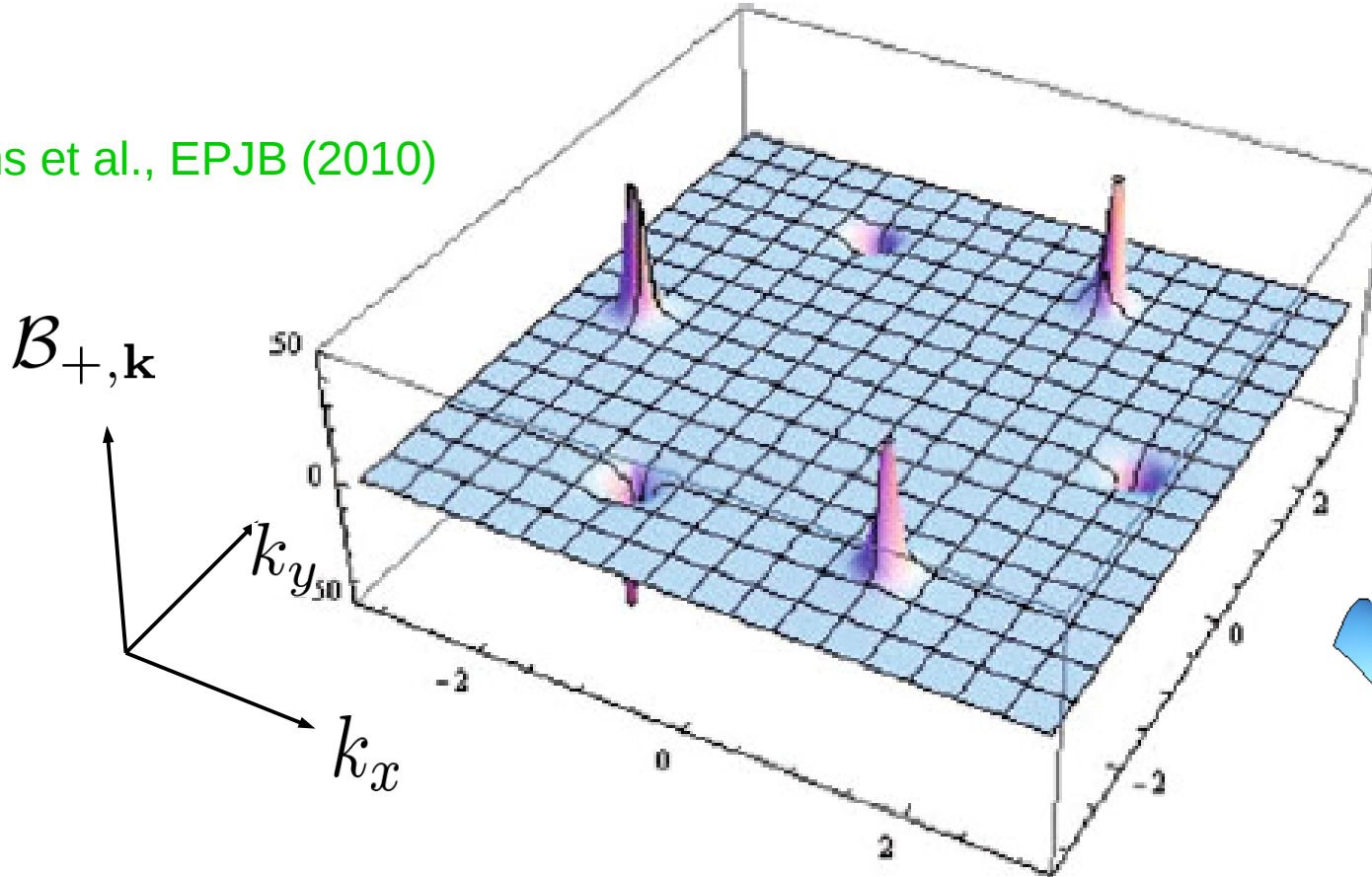
→ link to perturbation theory :

$$|u_n(\mathbf{k} + d\mathbf{k})\rangle = |u_n(\mathbf{k})\rangle + \sum_{m \neq n} |u_m(\mathbf{k})\rangle \frac{\langle u_m(\mathbf{k}) | d\mathbf{k} \cdot \nabla_{\mathbf{k}} H | u_n(\mathbf{k}) \rangle}{E_n(\mathbf{k}) - E_m(\mathbf{k})}$$



Berry curvature for insulating graphene

Fuchs et al., EPJB (2010)

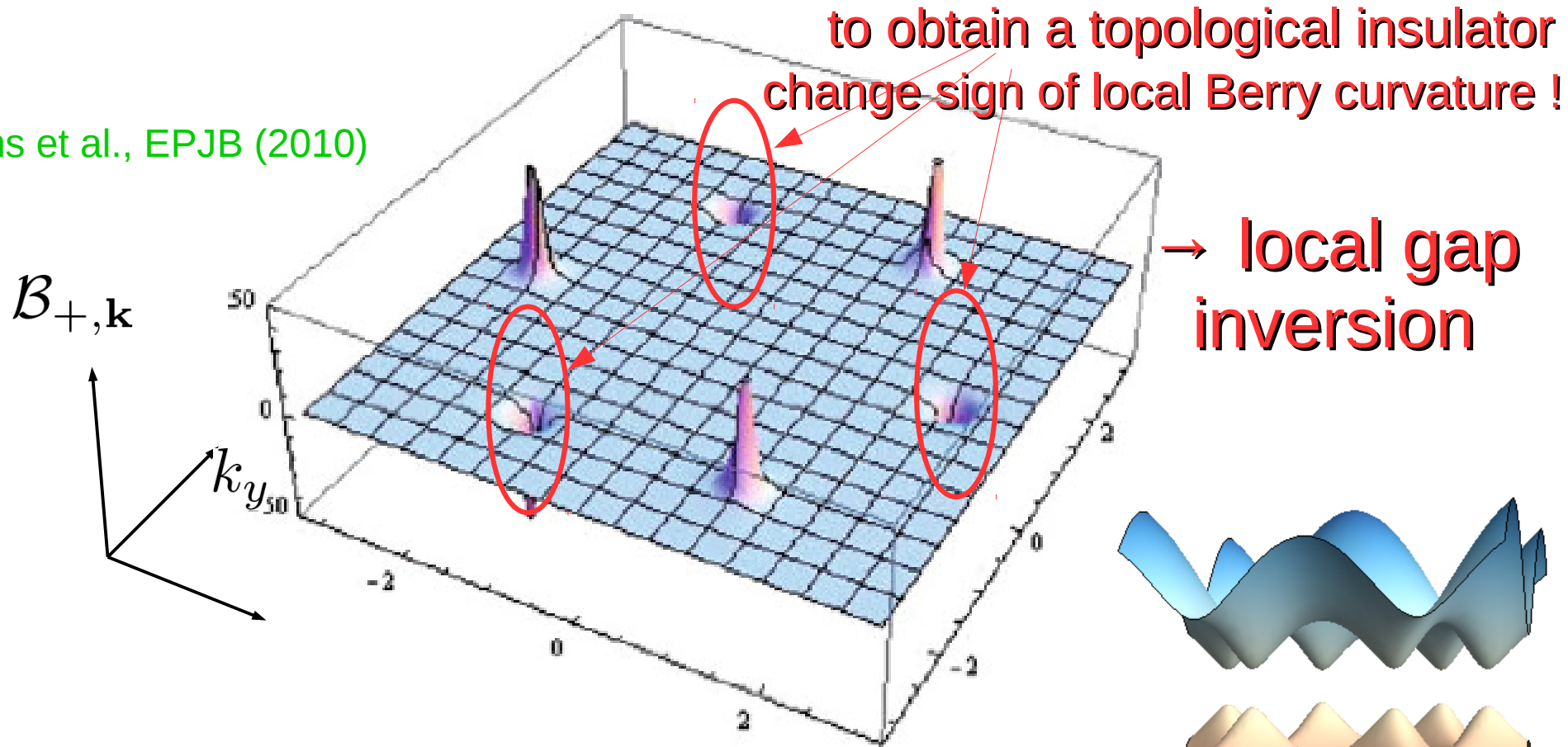


$$\mathcal{B}_+^\sigma(\mathbf{k}) = i\epsilon^{\sigma\mu\nu} \frac{\langle u_+ | \partial_{k_\mu} H(\mathbf{k}) | u_- \rangle \langle u_- | \partial_{k_\nu} H(\mathbf{k}) | u_+ \rangle}{[E_+(\mathbf{k}) - E_-(\mathbf{k})]^2}$$

Berry curvature concentrated around Dirac points

Berry curvature for insulating graphene

Fuchs et al., EPJB (2010)



$C_\lambda = 0$ Since curvature is antisymmetric

Berry curvature concentrated around Dirac points

Outline

- Introduction to Berry curvature and bulk-edge correspondence
- Dirac fermions and “half Chern numbers”
- 2D Model of a smooth interface – from chiral to massive *relativistic* interface states
- Weyl semimetals with smooth surfaces

Berry phase of a single Dirac point

Continuum Hamiltonian :
$$H_D = \begin{pmatrix} \sigma \Delta & \hbar v q e^{-i\xi\phi} \\ \hbar v q e^{i\xi\phi} & -\sigma \Delta \end{pmatrix}$$

$\xi = \pm$: *valley index (K and K')*

Berry connection:
$$\mathcal{A}_{\sigma,\lambda,\xi}(\mathbf{q}) = -\lambda \sigma \sin^2 \frac{\theta}{2} \xi \nabla_{\mathbf{q}} \phi$$

Berry curvature:
$$\mathcal{B}_{\sigma,\lambda,\xi}(\mathbf{q}) = -\frac{\lambda \sigma \xi}{2} \frac{\hbar^2 v^2 \Delta}{(\Delta^2 + \hbar^2 v^2 q^2)^{3/2}}$$

→ Berry phase:

$$\Gamma_{|q|} = -\pi \lambda \sigma \xi \left(1 - \frac{\Delta}{\sqrt{\Delta^2 + \hbar^2 v^2 q^2}} \right) \rightarrow -\pi \lambda \sigma \xi$$

→ **Chern number:**

$$C_{\lambda,\xi} = -\frac{1}{2} \lambda \sigma \xi \quad ???$$

“Half Chern number”

- Calculation in continuum limit
 - non-compact space (2D plane)
 - Dirac points arise necessarily in pairs !
[Nielsen and Ninomiya (1983)]
- Each (massive) Dirac point contributes $\pm 1/2$ to the total Chern number
 - in order to obtain a non-zero Chern number (per band), ***one needs an inverted gap***

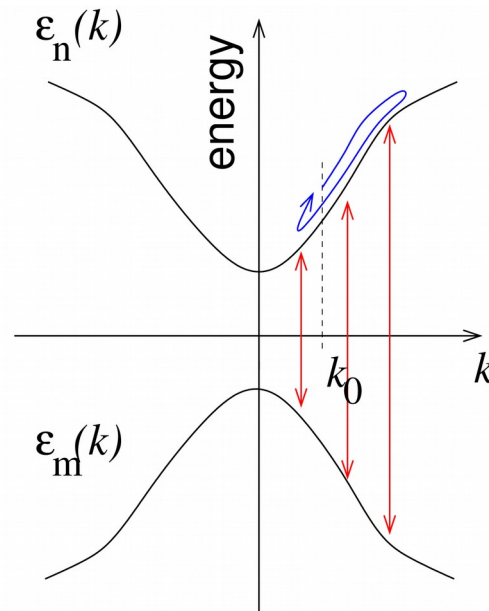
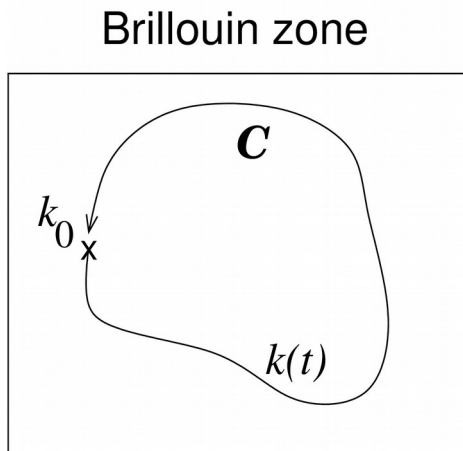
$$\sigma \rightarrow \sigma(\xi) = \sigma\xi$$

Berry curvature of a massive Dirac fermion → correlations

$$\mathcal{B}_{\sigma,\lambda,\xi}(\mathbf{q}) = -\frac{\lambda\sigma\xi}{2} \frac{\hbar^2 v^2 \Delta}{(\Delta^2 + \hbar^2 v^2 q^2)^{3/2}} \quad \begin{matrix} \mathbf{q} \rightarrow 0 \\ \rightarrow \end{matrix} \quad -\frac{\lambda\sigma\xi}{2} \ell_C^2$$

$$\ell_C = \frac{\hbar v}{\Delta} = \frac{\hbar}{m_D v} \quad : \text{effective Compton length}$$

→ “minimal” length scale



Berry curvature of a massive Dirac fermion → correlations

$$\mathcal{B}_{\sigma,\lambda,\xi}(\mathbf{q}) = -\frac{\lambda\sigma\xi}{2} \frac{\hbar^2 v^2 \Delta}{(\Delta^2 + \hbar^2 v^2 q^2)^{3/2}} \quad \begin{array}{l} \mathbf{q} \rightarrow 0 \\ \rightarrow \end{array} \quad -\frac{\lambda\sigma\xi}{2} \ell_C^2$$

$$\ell_C = \frac{\hbar v}{\Delta} = \frac{\hbar}{m_D v} \quad : \text{effective Compton length}$$

→ Berry curvature corrections
in exciton spectra of 2D TMDC

Zhou et al., PRL (2015)
Srivastava & Imamoglu, PRL (2015)
Trushin, MOG, Belzig, PRL (2018)
Hishri, Jaziri, MOG, arXiv (2018)

→ Stability of matter,
breakdown effects for

$$\alpha^* > 1$$

→ “minimal” length scale

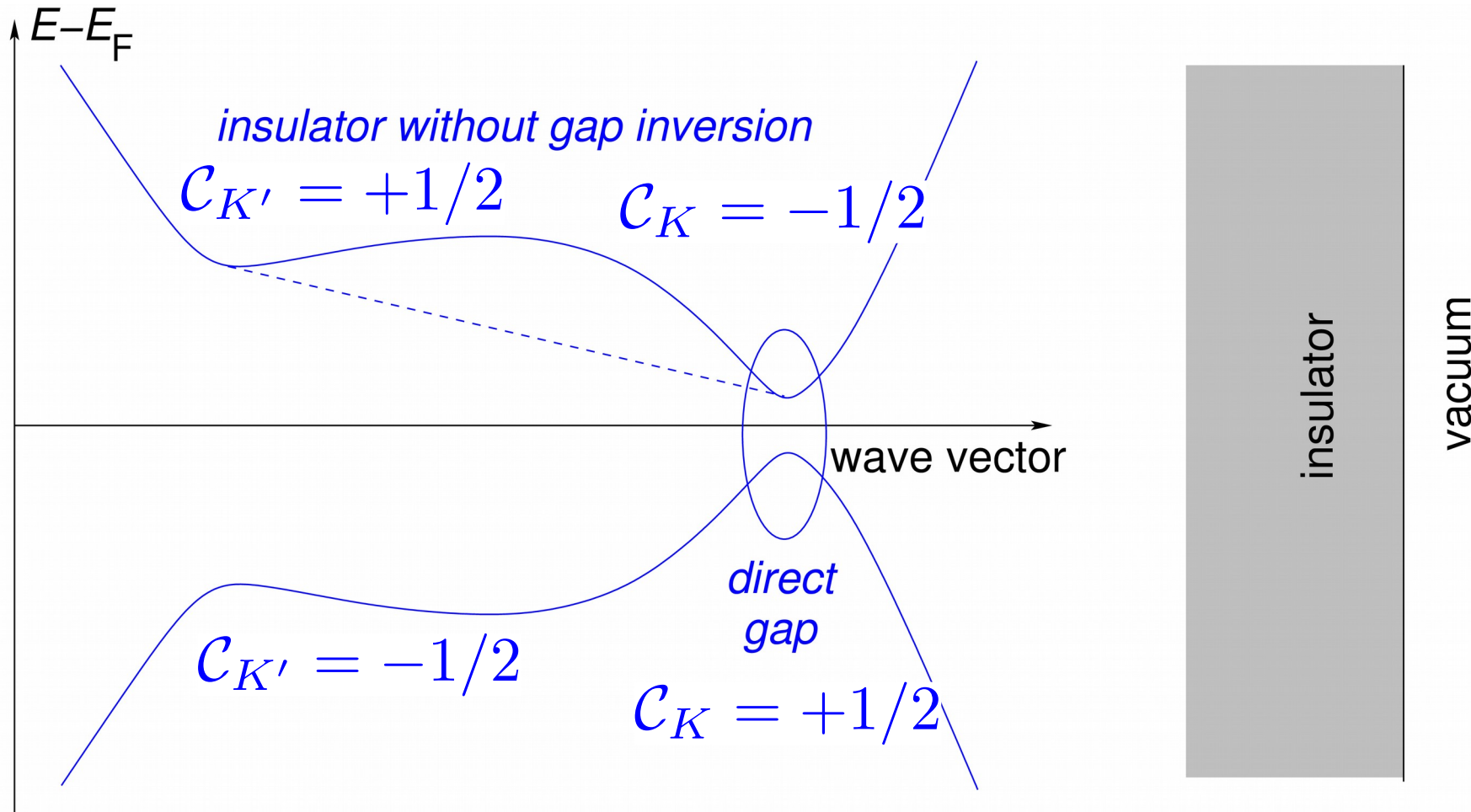
→ important for *correlations*

$$\ell_C = \alpha^* a_B^*$$

$$\alpha^* = \frac{e^2}{\hbar \epsilon v} \quad \text{effective fine-structure constant}$$

$$a_B^* = \frac{\hbar^2 \epsilon}{m_D e^2} \quad \text{effective Bohr radius}$$

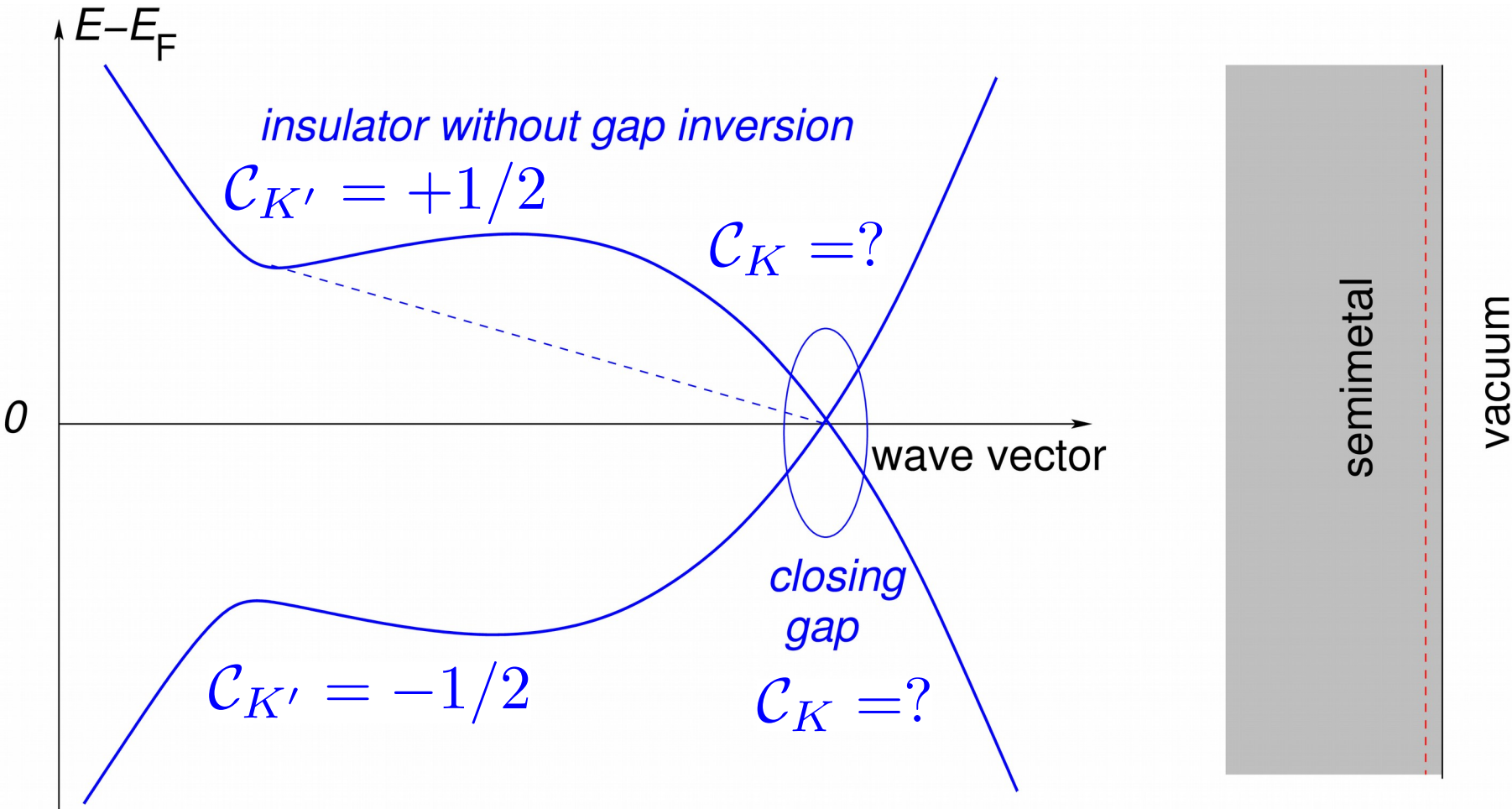
Haldane model (broken time-reversal symmetry, 1988)



Broken TR symmetry : $E(\mathbf{k}) \neq E(-\mathbf{k})$

modify Dirac points independently from one another

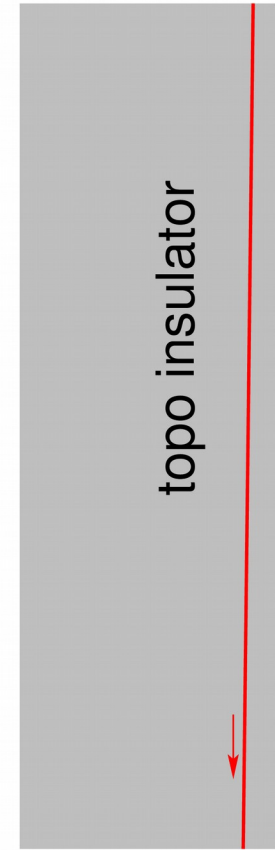
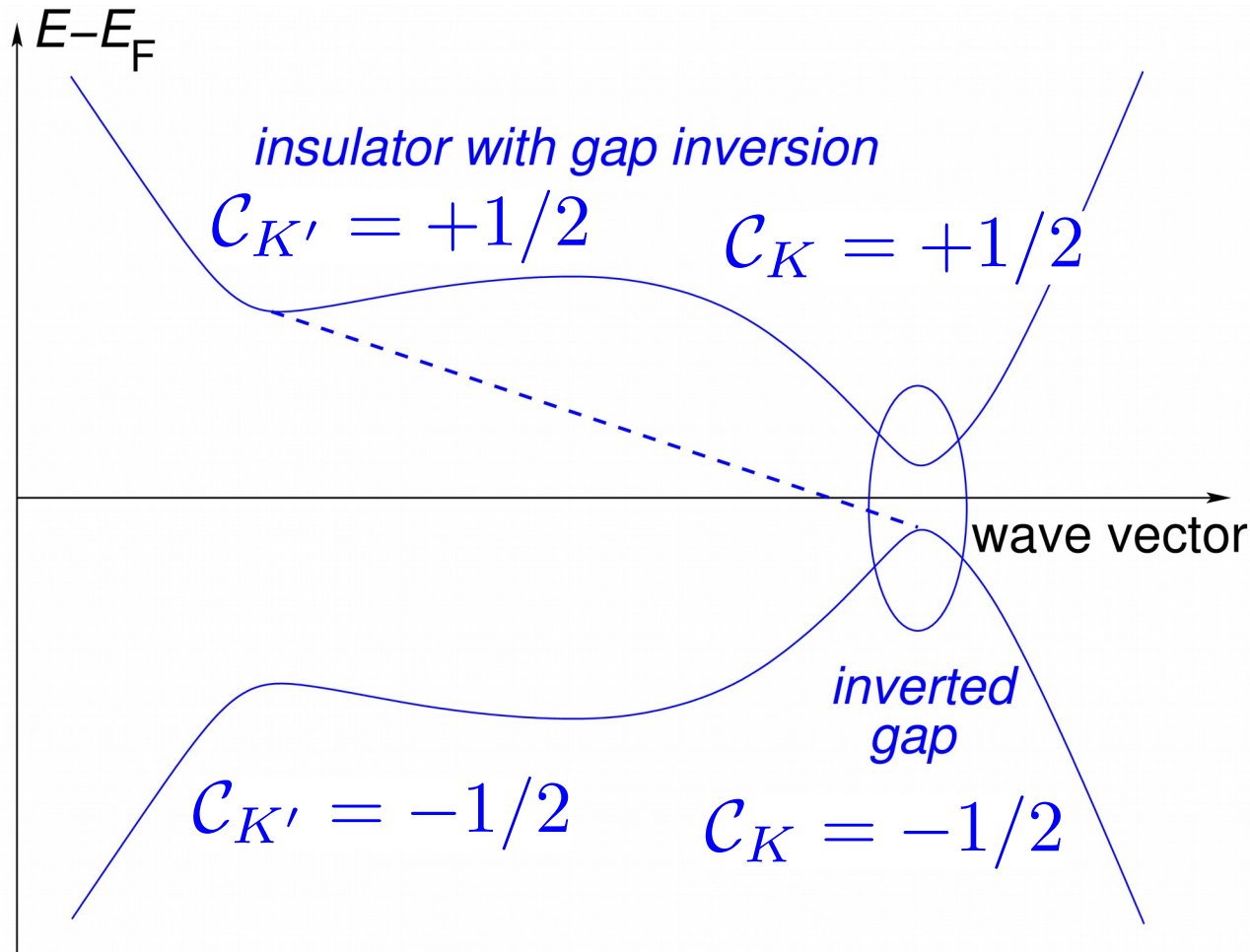
Haldane model (broken time-reversal symmetry, 1988)



Broken TR symmetry : $E(\mathbf{k}) \neq E(-\mathbf{k})$

modify Dirac points independently from one another

Haldane model (broken time-reversal symmetry, 1988)



Broken TR symmetry : $E(\mathbf{k}) \neq E(-\mathbf{k})$

Change in total Chern number: $\Delta C = \Delta C_K = \pm 1$



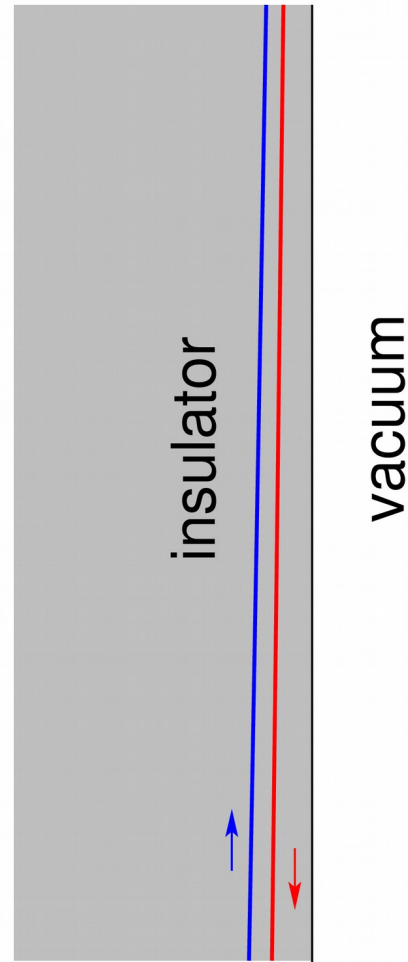
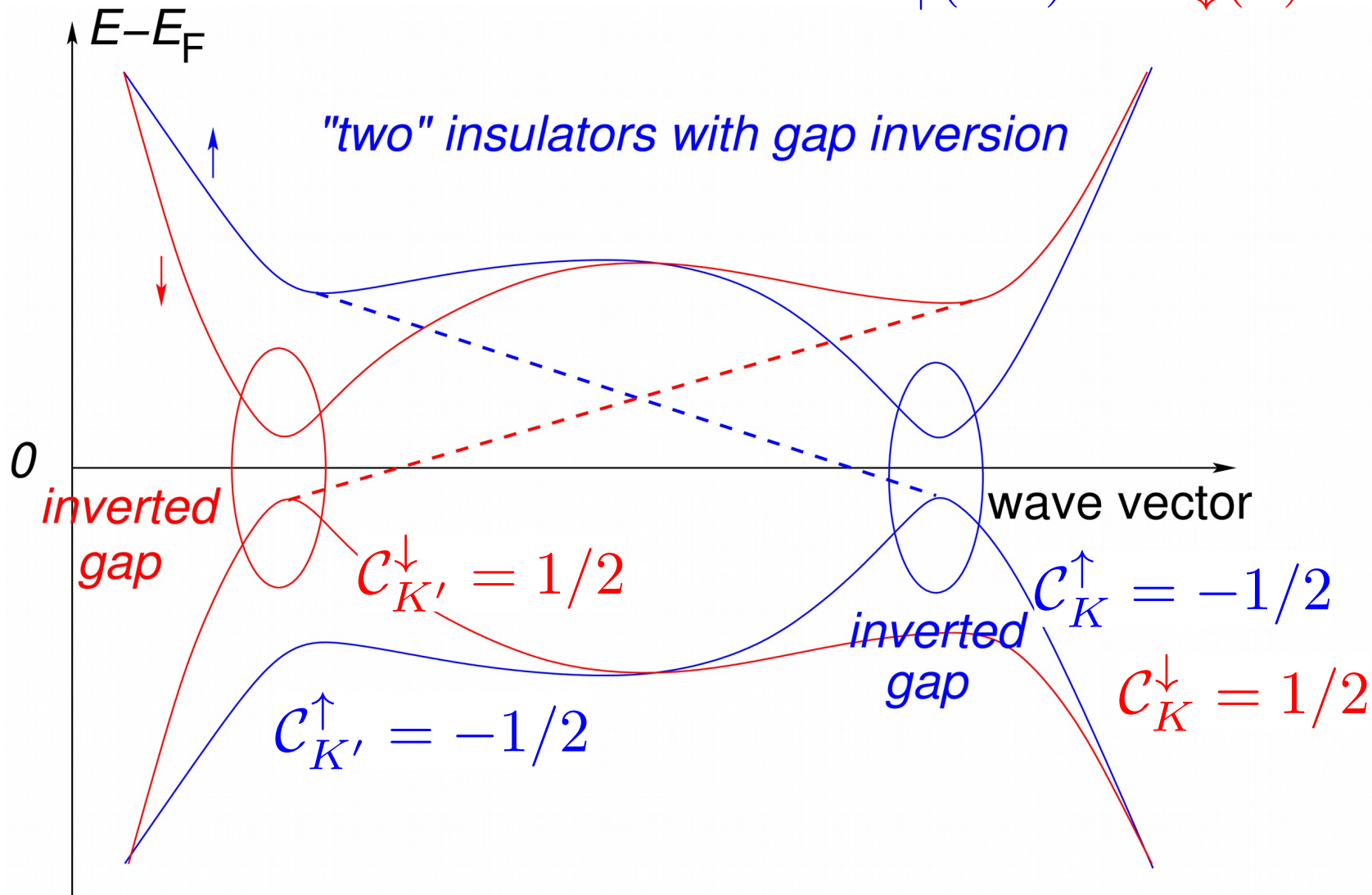
Kane-Mele model (2005)

→ TR symmetry respected



profit from spin !

$$E_{\uparrow}(-\mathbf{k}) = E_{\downarrow}(\mathbf{k})$$





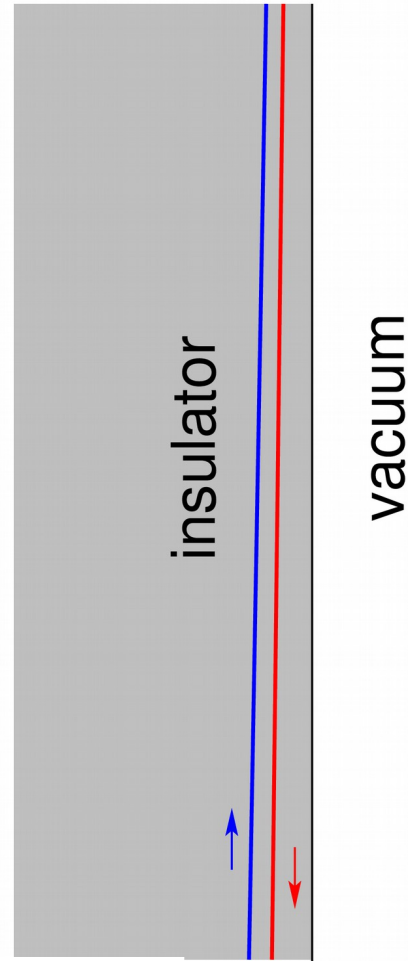
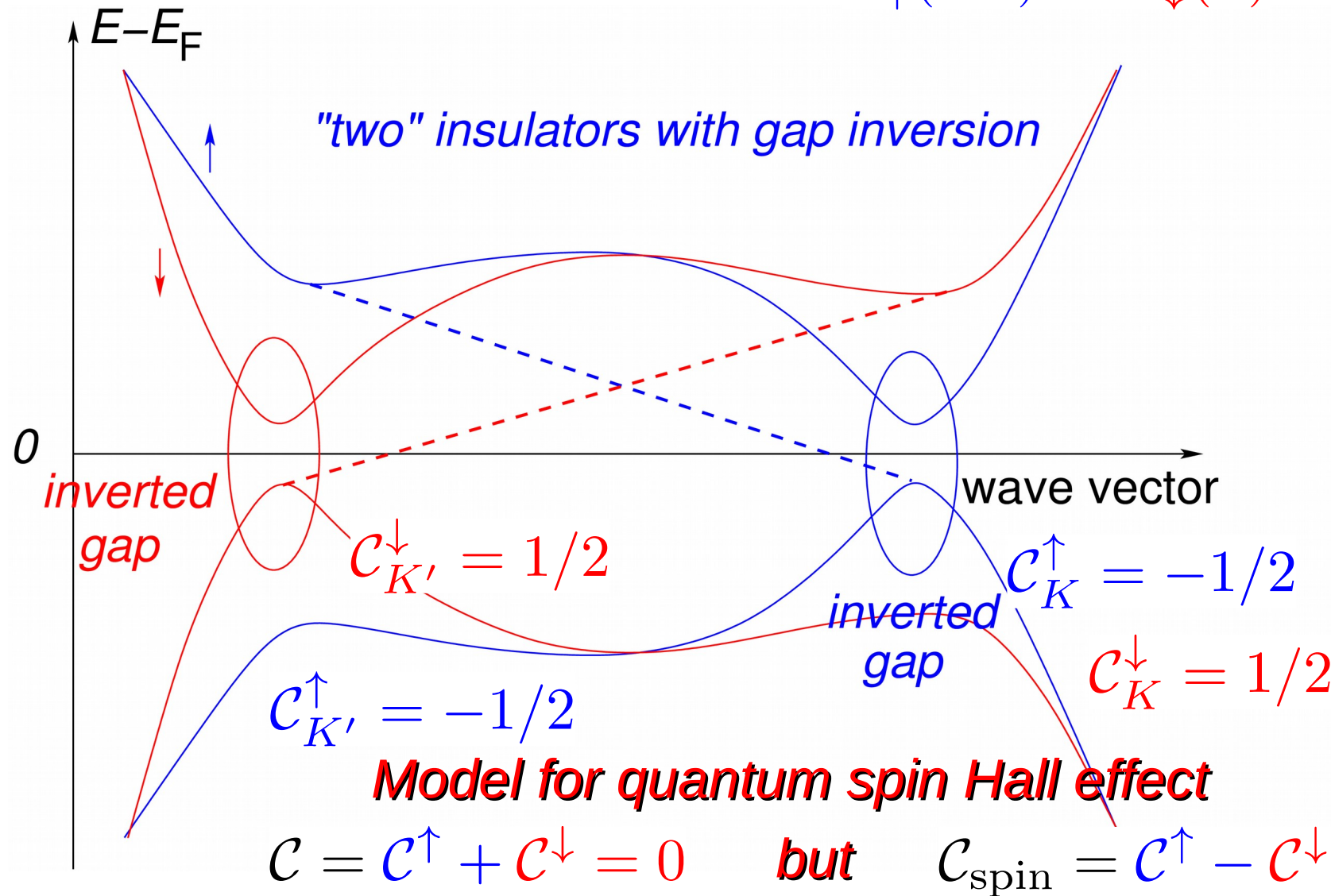
Kane-Mele model (2005)

→ TR symmetry respected



profit from spin !

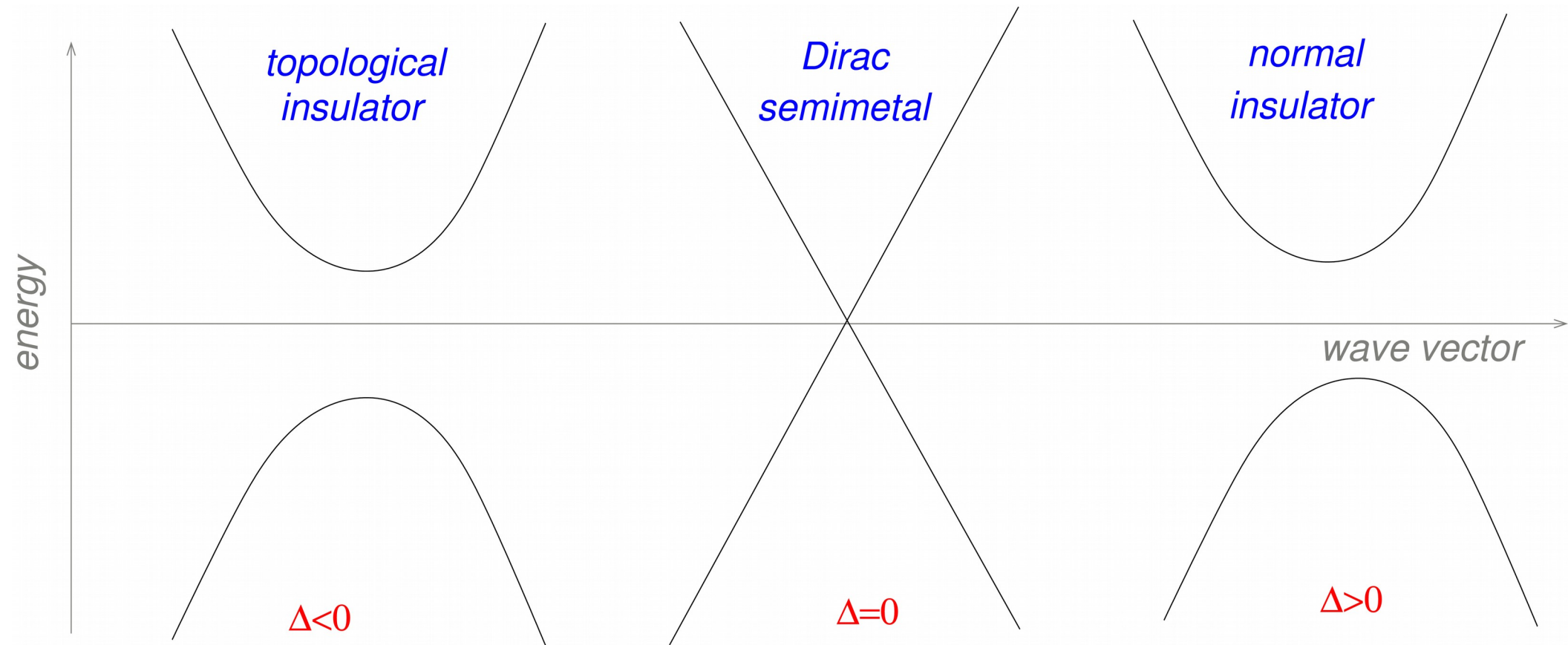
$$E_{\uparrow}(-\mathbf{k}) = E_{\downarrow}(\mathbf{k})$$



Outline

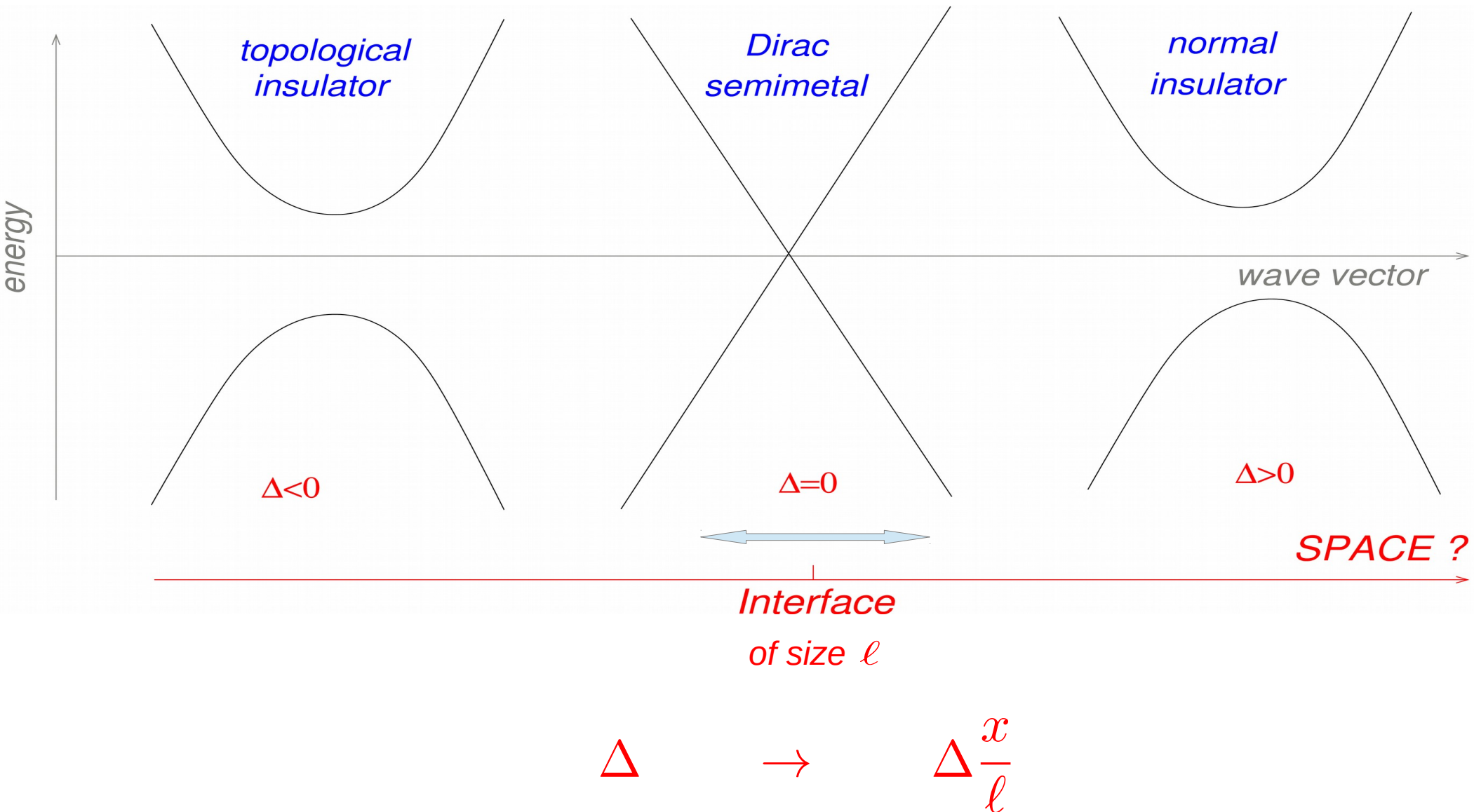
- Introduction to Berry curvature and bulk-edge correspondence
- Dirac fermions and “half Chern numbers”
- **2D Model of a smooth interface – from chiral to massive *relativistic* interface states**
- Weyl semimetals with smooth surfaces

How can we use this to describe an interface ?

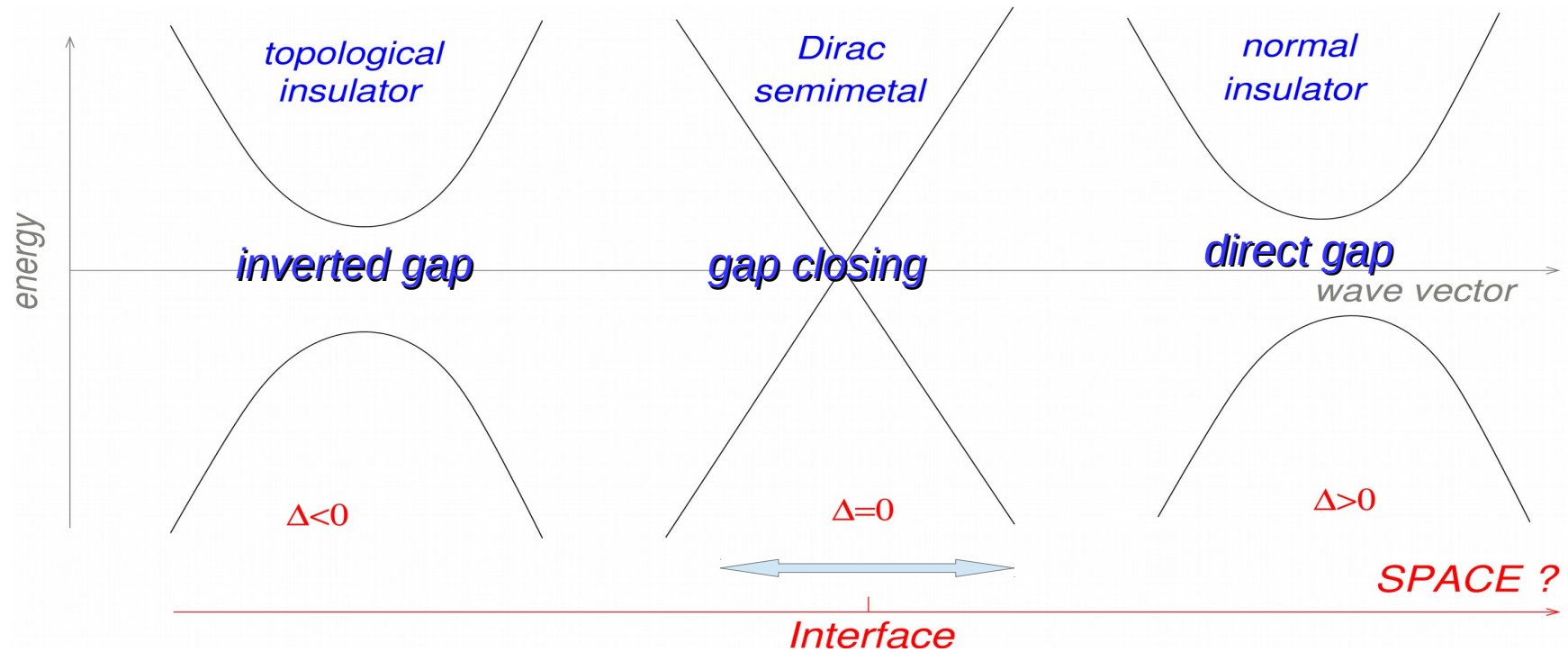


in parameter space

How can we use this to describe an interface ?



Simplified 2D model of a smooth interface (*topological heterojunction*)



$$H = \begin{pmatrix} \Delta \frac{x}{\ell} & \hbar v (q_x - i q_y) \\ \hbar v (q_x + i q_y) & -\Delta \frac{x}{\ell} \end{pmatrix}$$

Sign change in an interface of size ℓ

Simplified 2D model of a smooth interface (*topological heterojunction*)

Change of “quantization axis” (unitary trafo)

$$\sigma_z \rightarrow -\sigma_y, \quad \sigma_y \rightarrow \sigma_z$$

$$H = \hbar \begin{pmatrix} vq_y & v(q_x + i\frac{x}{\ell_S^2}) \\ v(q_x - i\frac{x}{\ell_S^2}) & -vq_y \end{pmatrix}$$

With characteristic (~”magnetic”) length: $\ell_S = \sqrt{\hbar v / \Delta} = \sqrt{\ell \xi}$

(intrinsic length: $\xi = \hbar v / \Delta$)

solution via ladder operators of harmonic oscillator:

$$\hat{a} = \frac{\ell_S}{\sqrt{2}} (q_x + ix/\ell_S^2) \quad \hat{a}^\dagger = \frac{\ell_S}{\sqrt{2}} (q_x - ix/\ell_S^2) \quad [\hat{a}, \hat{a}^\dagger] = 1$$

Simplified 2D model of a smooth interface (*topological heterojunction*)

→ Hamiltonian of massive Dirac fermions in a magnetic field

$$H = \begin{pmatrix} \hbar v q_y & \sqrt{2} \hbar \frac{v}{\ell_S} \hat{a} \\ \sqrt{2} \hbar \frac{v}{\ell_S} \hat{a}^\dagger & -\hbar v q_y \end{pmatrix}$$

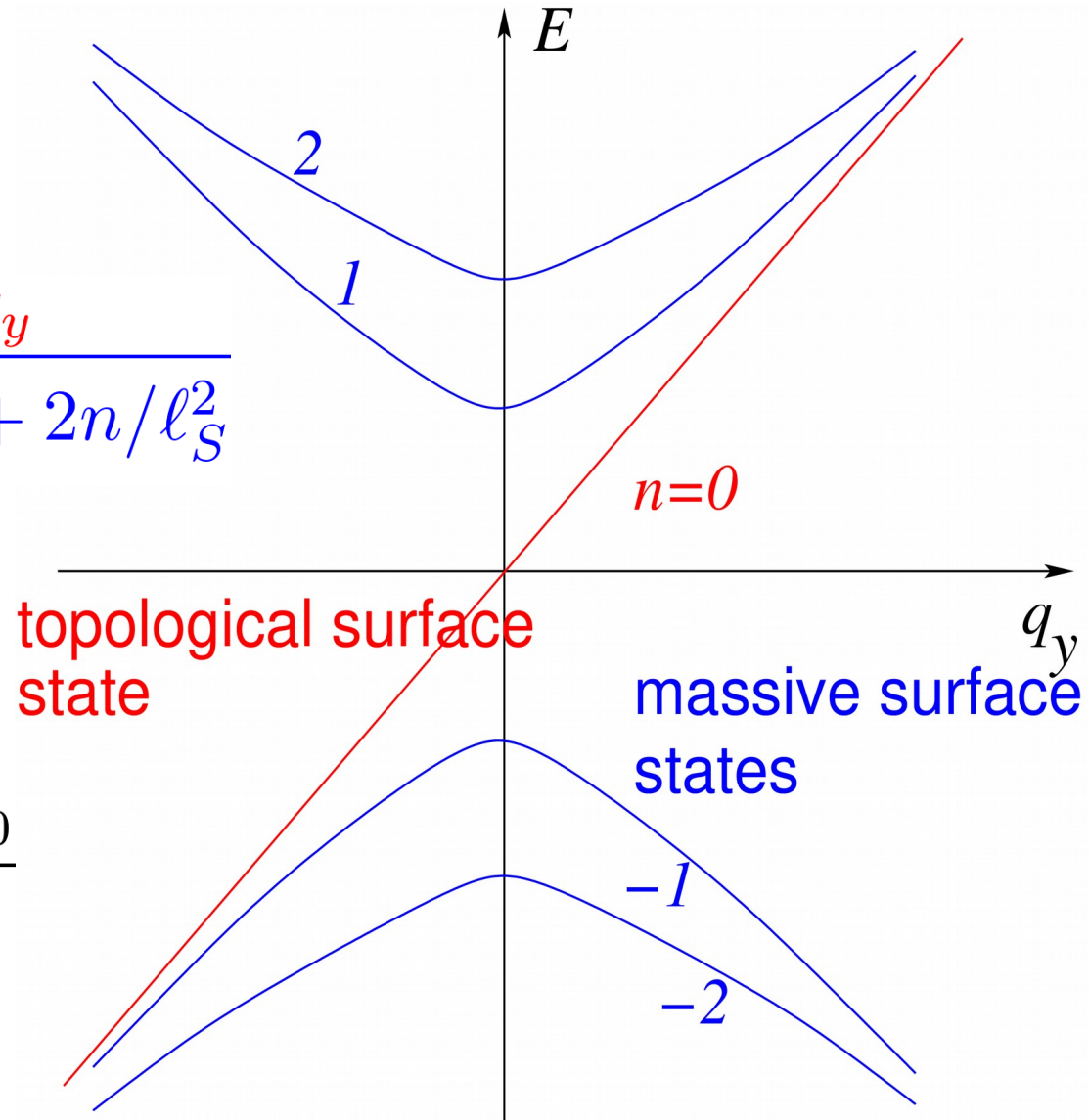
surface states ~ Landau levels

$$\begin{aligned} E_{n=0} &= v q_y \\ E_{\lambda, n \neq 0} &= \lambda v \sqrt{q_y^2 + 2n/\ell_S^2} \end{aligned}$$

Surface (edge) states

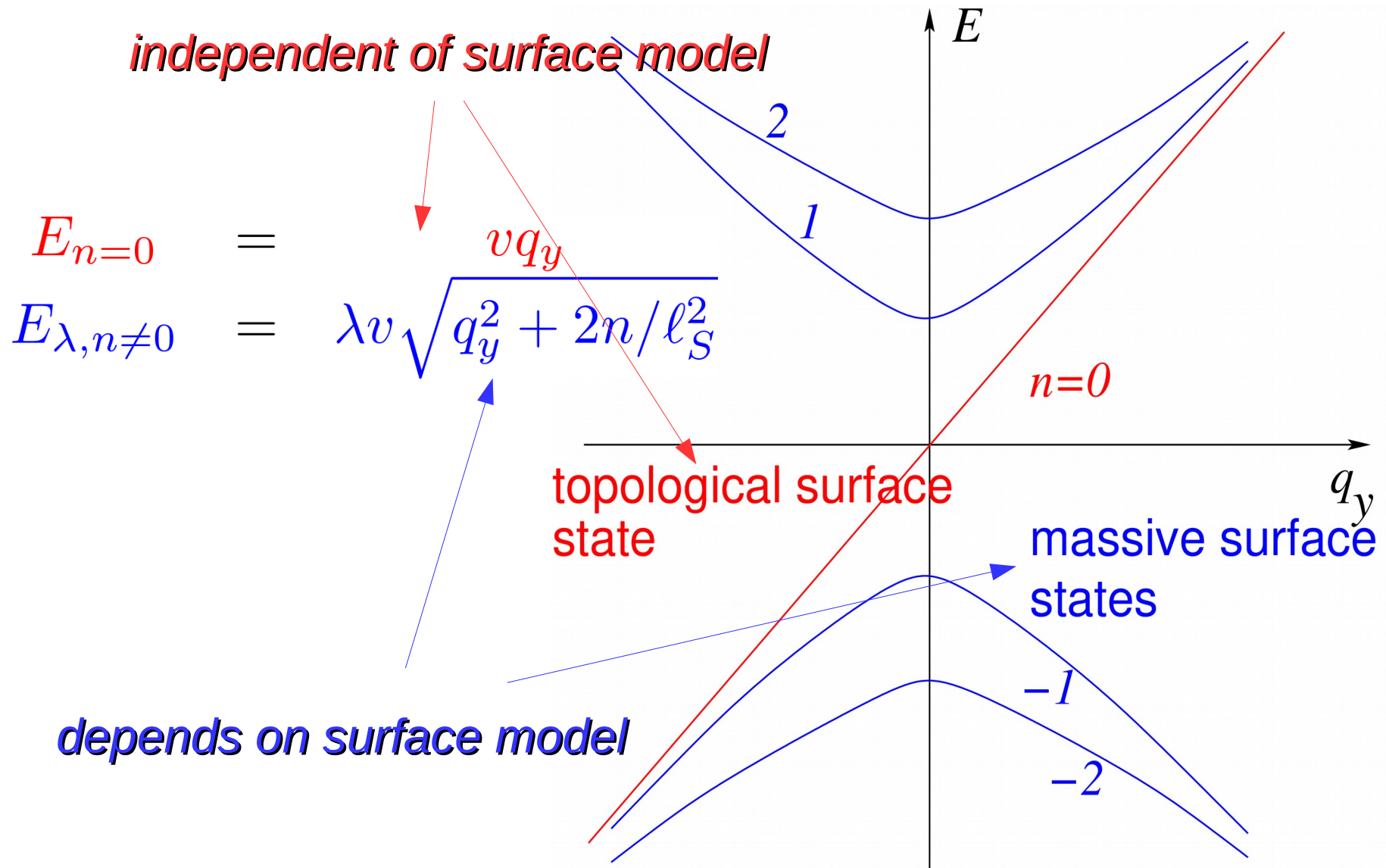
$$E_{n=0} = vq_y$$

$$E_{\lambda, n \neq 0} = \lambda v \sqrt{q_y^2 + 2n/\ell_S^2}$$



chirality : sign of $\frac{\partial E_0}{\partial q_y}$

Surface (edge) states



Surface (edge) states

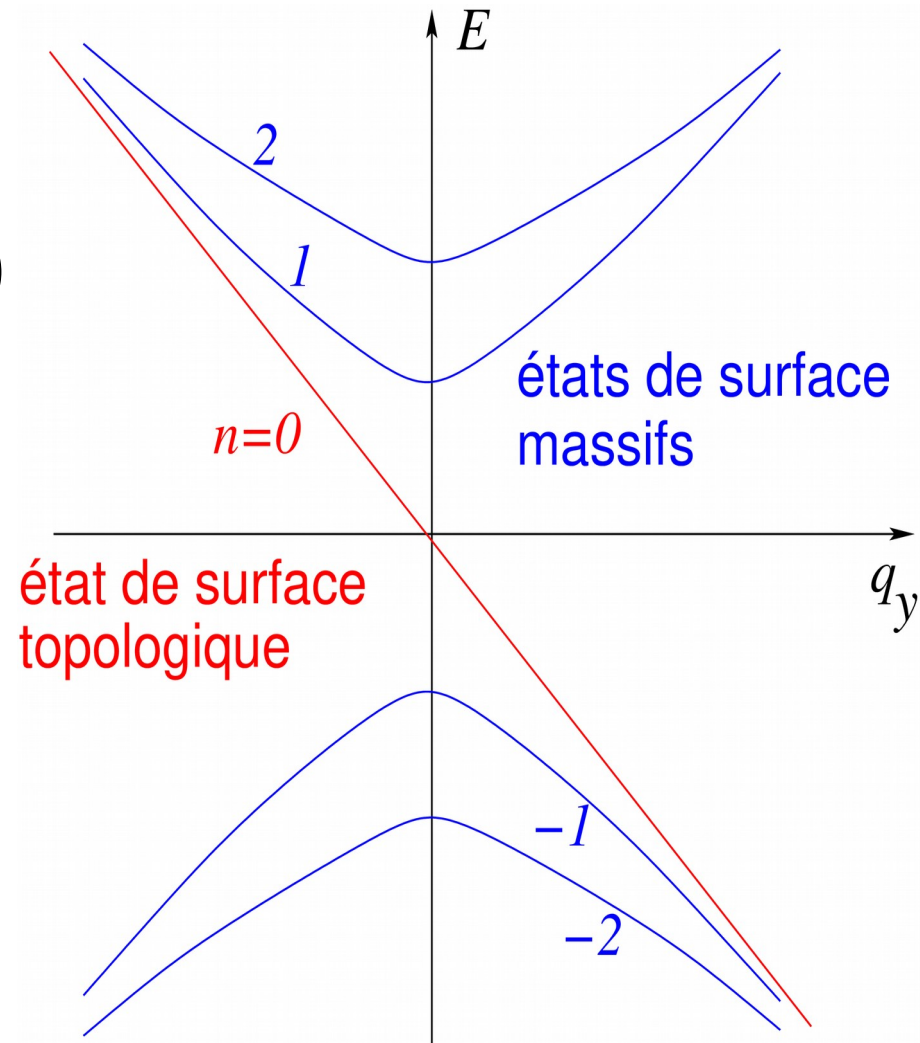
- How to change sign of chirality:

→ changing the valley (for helical edge states with spin)

$$\xi \rightarrow -\xi$$

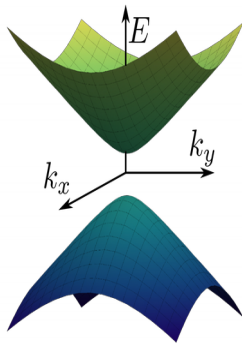
→ changing the edge (~ flipping orientation of “magnetic field”)

$$l \rightarrow -l$$



Surface states in 3D materials

➤ e.g. PbTe/SnTe and HgTe/CdTe interfaces : gap switches sign



Complication in 3D: 4x4 Hamiltonian

$$\ell_S^2 = \ell \xi = \ell \frac{\hbar v_F}{\Delta}$$

$$H = v_F(k_z \parallel \otimes \tau_y + (k_y \sigma_x - k_x \sigma_y) \otimes \tau_x) + \Delta(z) \parallel \otimes \tau_z$$

here: $\Delta(z) = \Delta \tanh(z/\ell)$

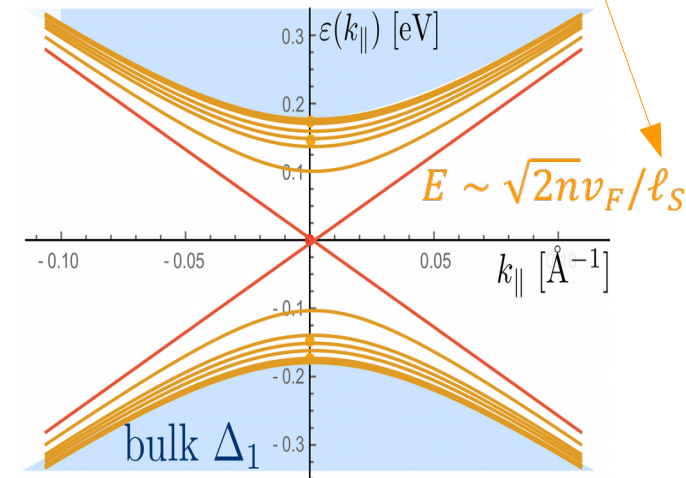
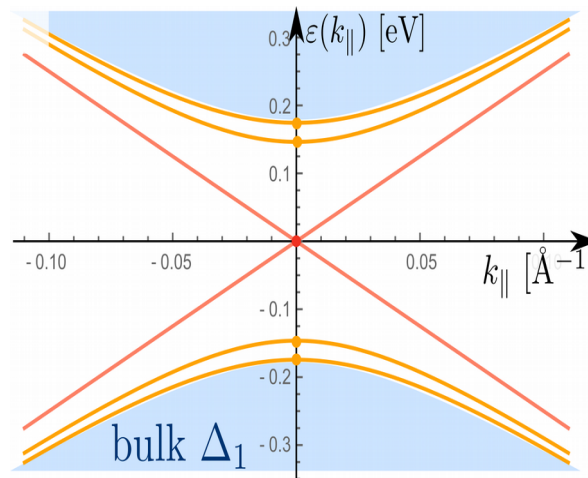
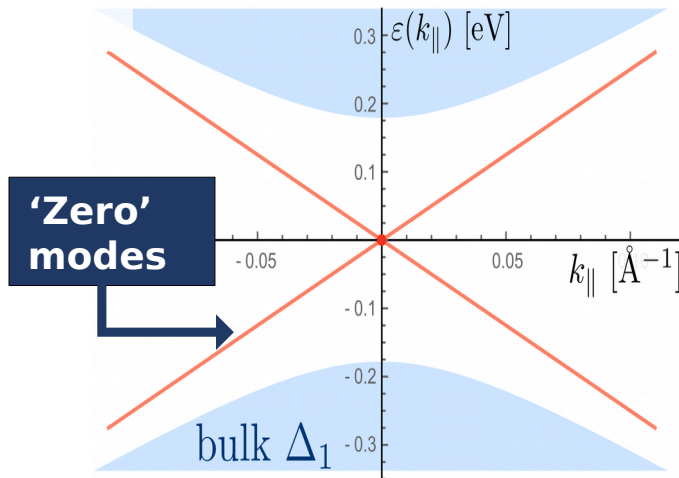
+ numerical k.p calculations (→ ENS Lyon)

ℓ/ξ

abrupt

intermediate

very smooth



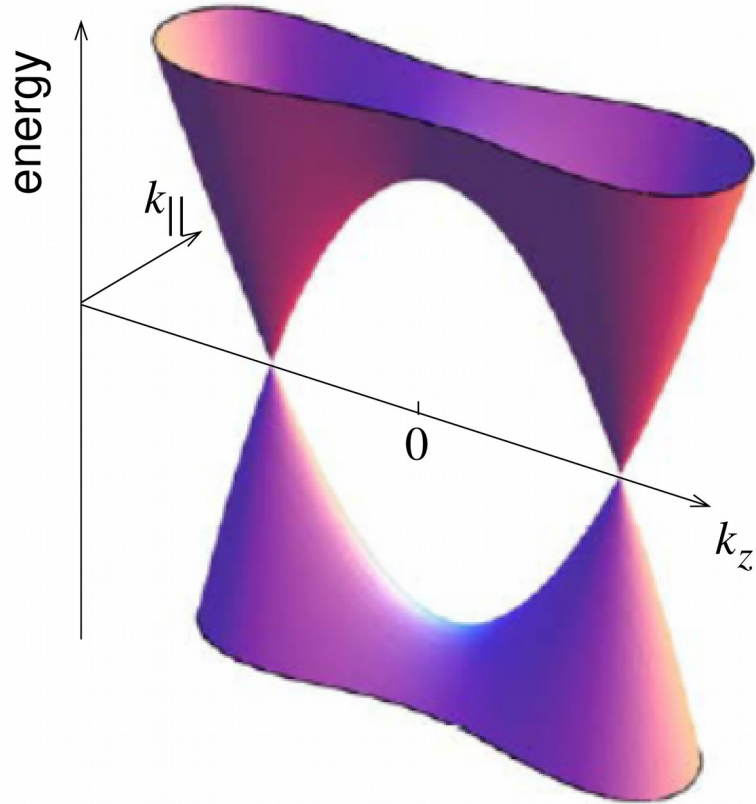
Conclusions

- Surface states of topological materials with smooth interfaces ~ Landau bands of Dirac fermions
- Topologically protected surface state ~ **chiral $n=0$ Landau band**
- Additional **massive** Landau bands ($n \neq 0$)
- ***Intriguing relativistic effects***
- ***Experimental evidence in HgTe samples***

Outline

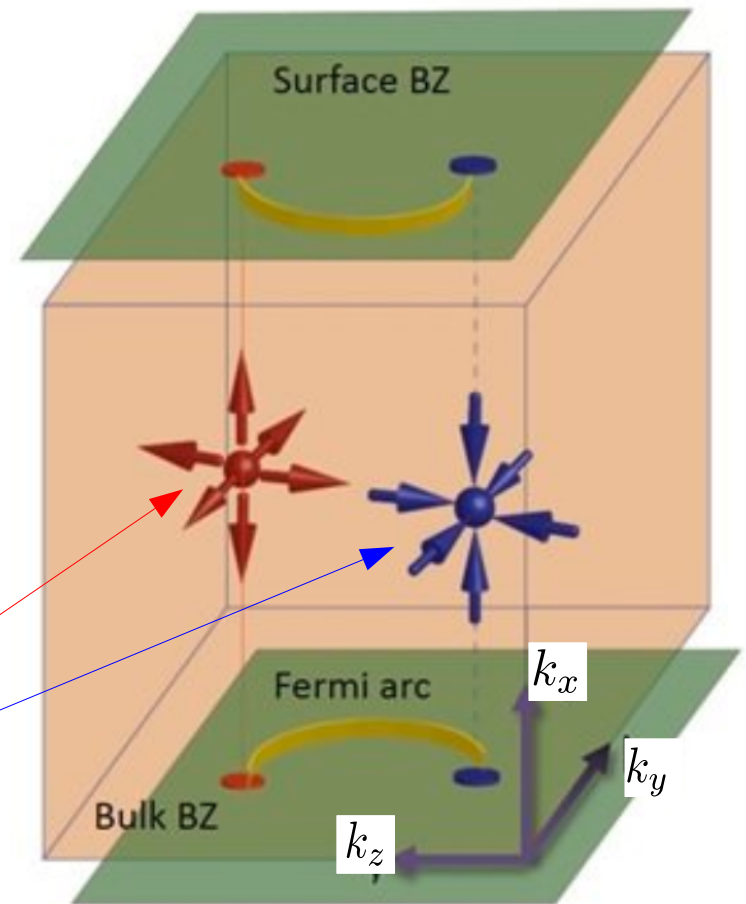
- Introduction to Berry curvature and bulk-edge correspondence
- Dirac fermions and “half Chern numbers”
- 2D Model of a smooth interface – from chiral to massive *relativistic* interface states
- **Weyl semimetals with smooth surfaces**

Weyl semimetals – “3D graphene”

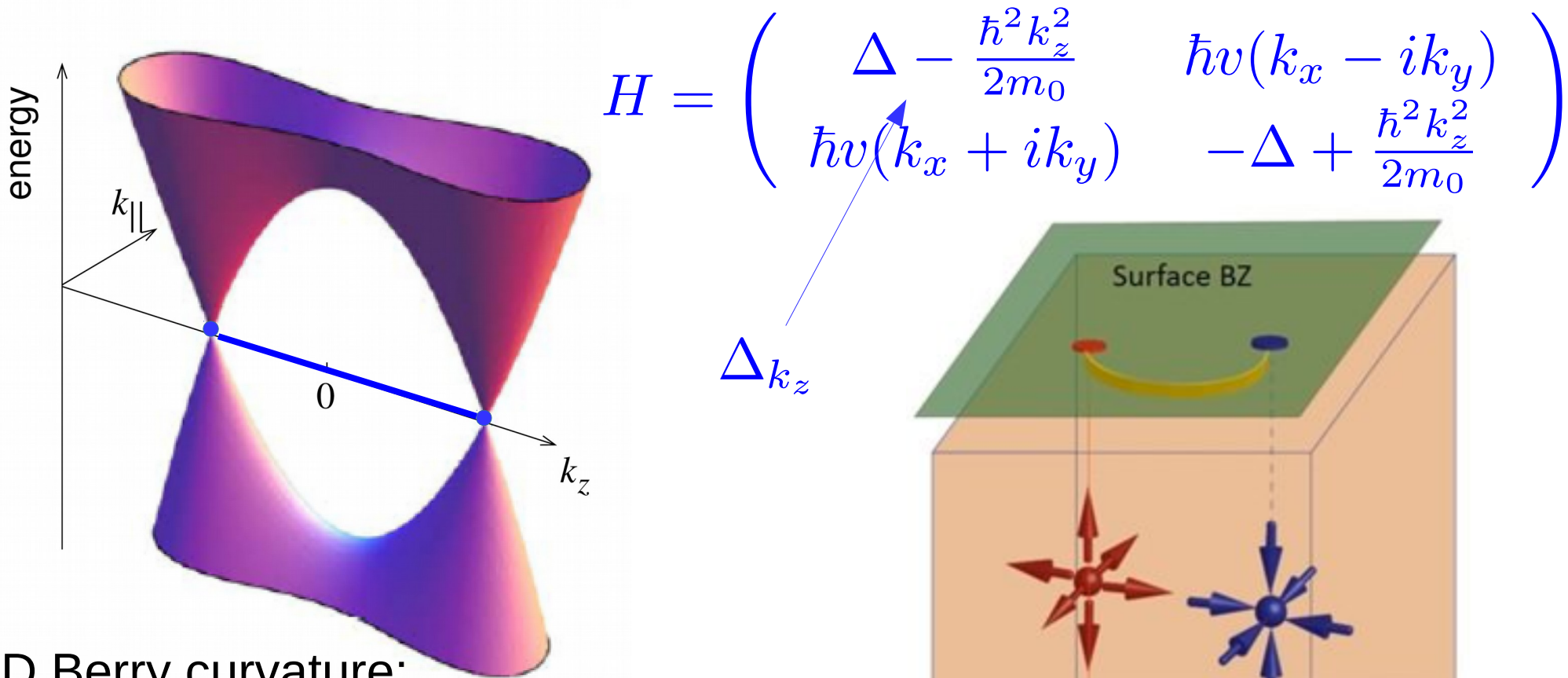


$$H = \begin{pmatrix} \Delta - \frac{\hbar^2 k_z^2}{2m_0} & \hbar v(k_x - ik_y) \\ \hbar v(k_x + ik_y) & -\Delta + \frac{\hbar^2 k_z^2}{2m_0} \end{pmatrix}$$

Dirac monopoles
(in wave function)



Weyl semimetals – “3D graphene”

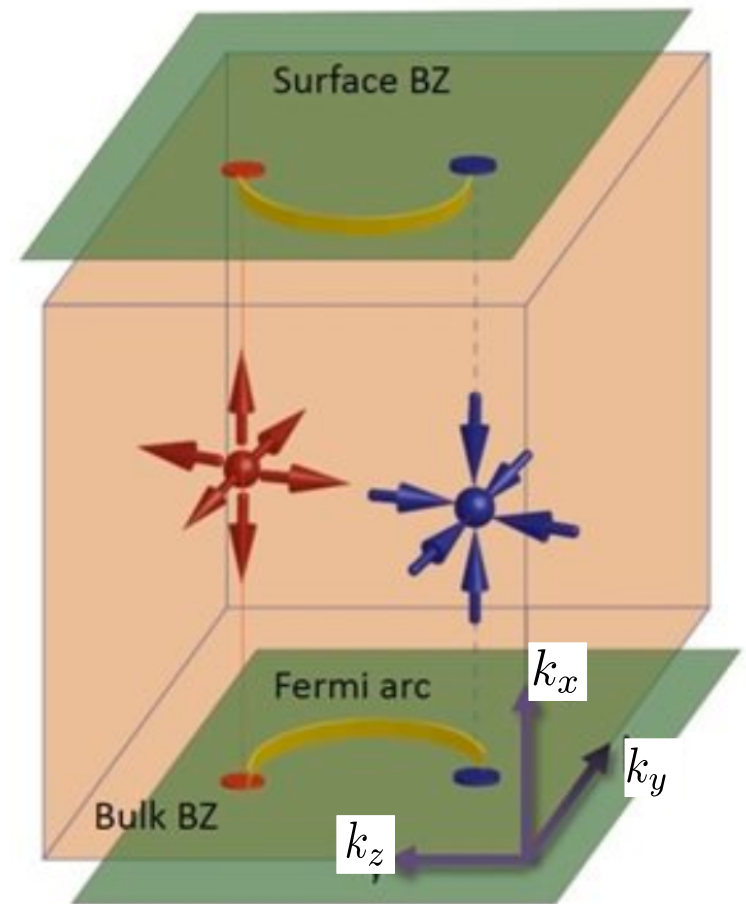


2D Berry curvature:

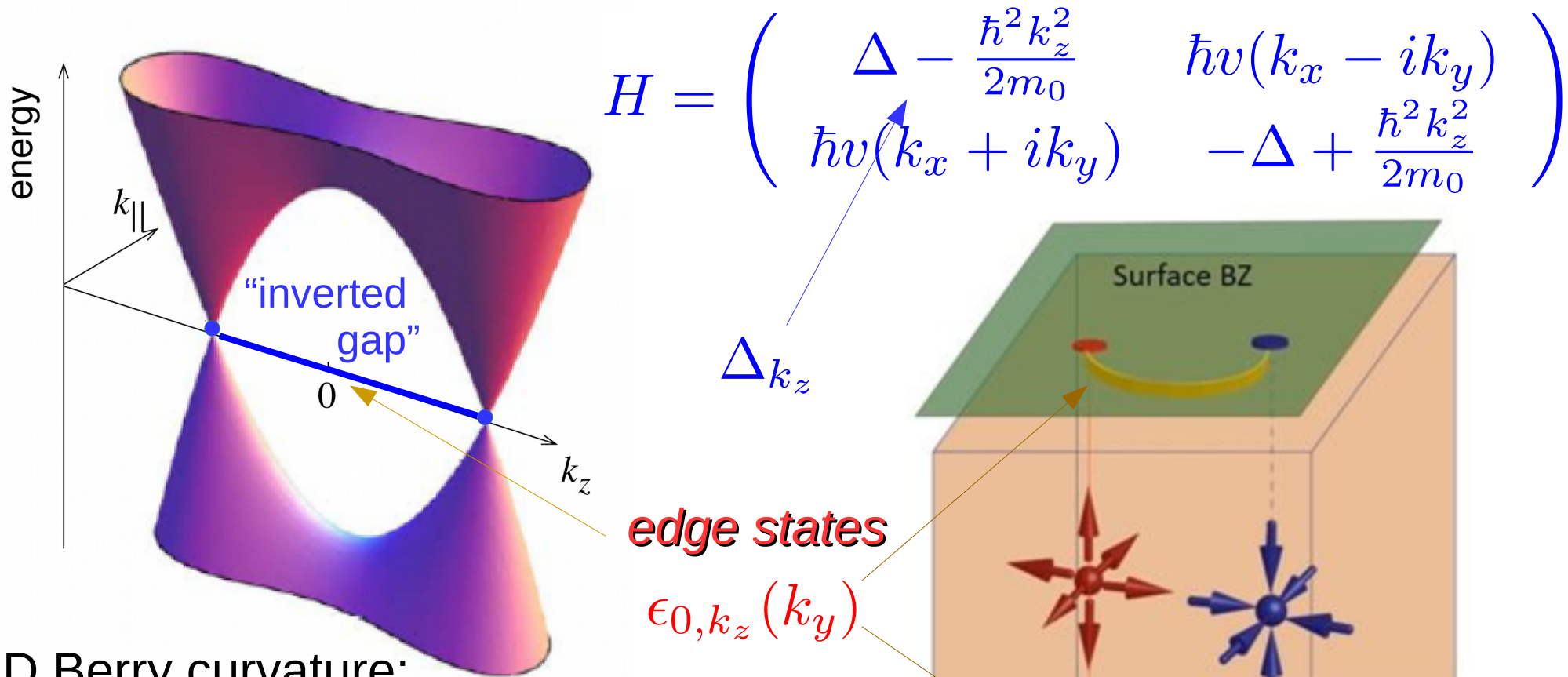
$$\mathcal{B}_{\lambda, k_z}(k_{||}) = -\frac{\lambda}{2} \frac{\hbar^2 v^2 \Delta k_z}{(\Delta_{k_z}^2 + \hbar^2 v^2 k_{||}^2)^{3/2}}$$

“half Chern number”:

$$C_{\lambda}(k_z) = -\frac{1}{2} \lambda \operatorname{sgn}(\Delta_{k_z})$$



Weyl semimetals – “3D graphene”

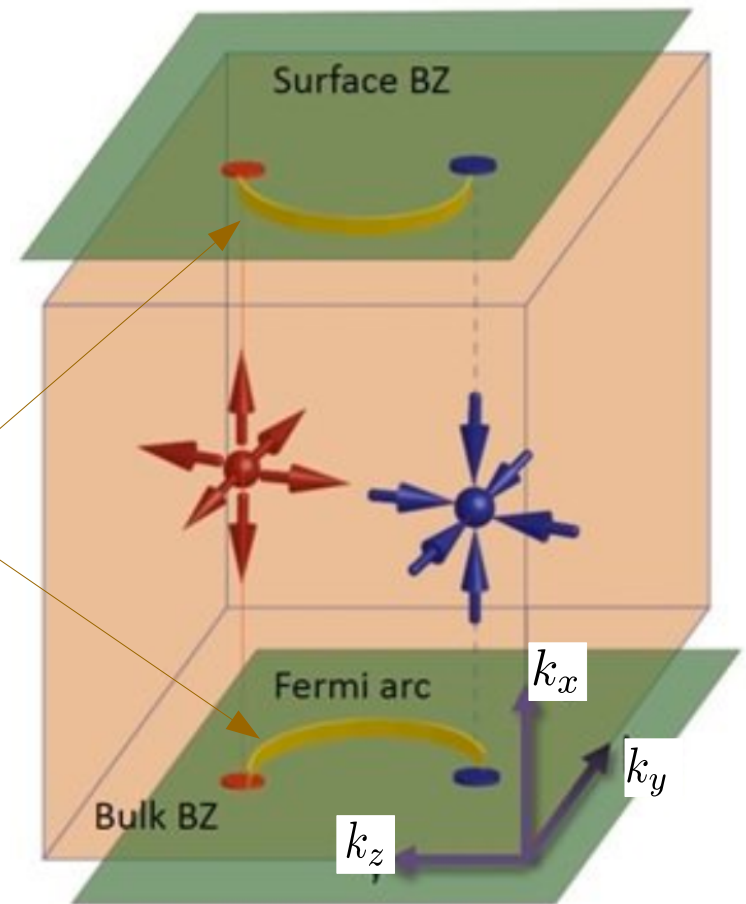


2D Berry curvature:

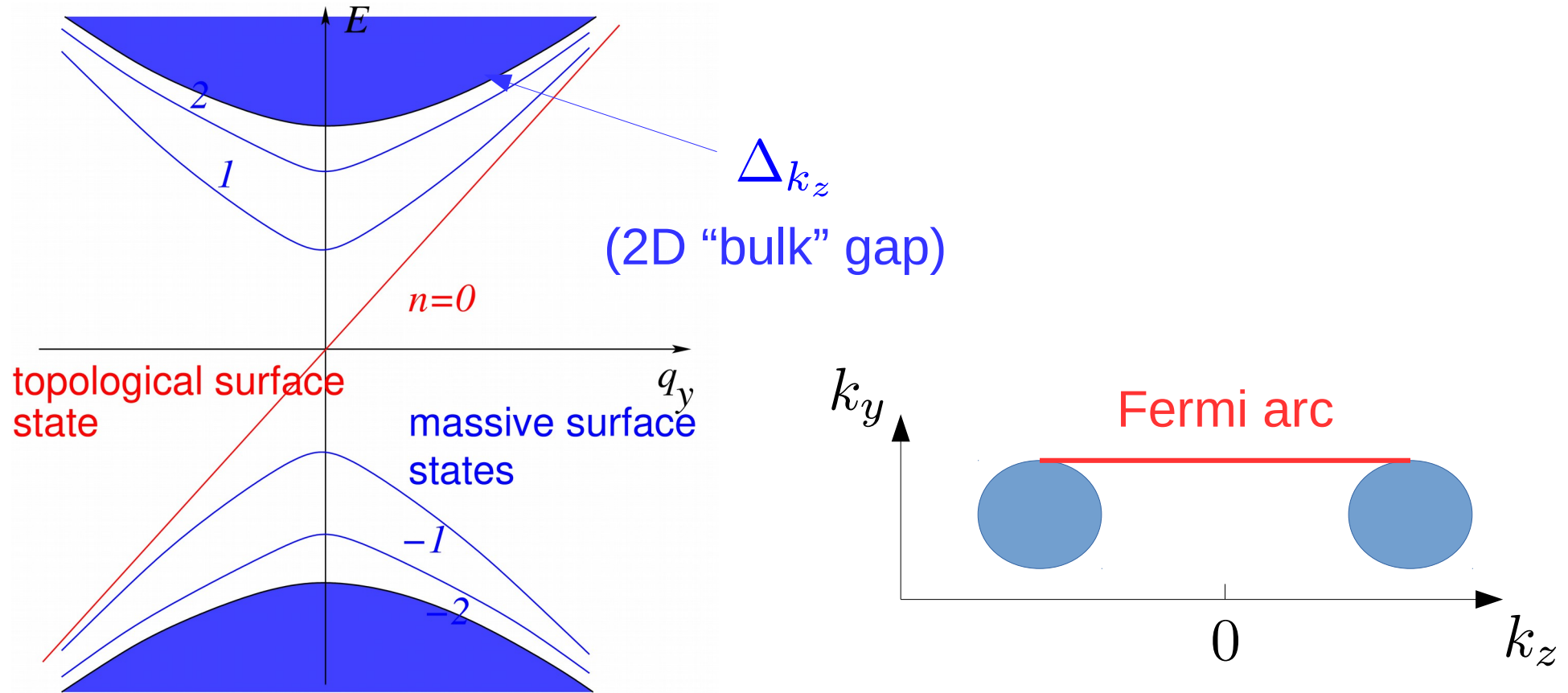
$$\mathcal{B}_{\lambda,k_z}(k_{\parallel}) = -\frac{\lambda}{2} \frac{\hbar^2 v^2 \Delta k_z}{(\Delta_{k_z}^2 + \hbar^2 v^2 k_{\parallel}^2)^{3/2}}$$

“half Chern number”:

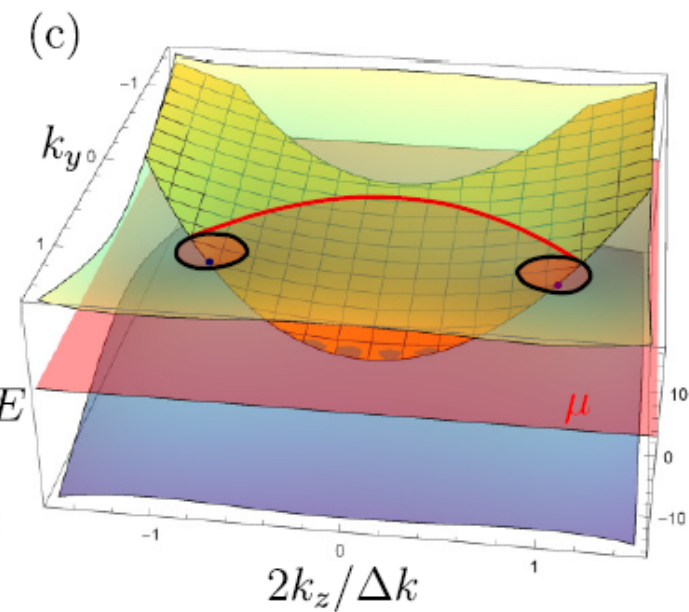
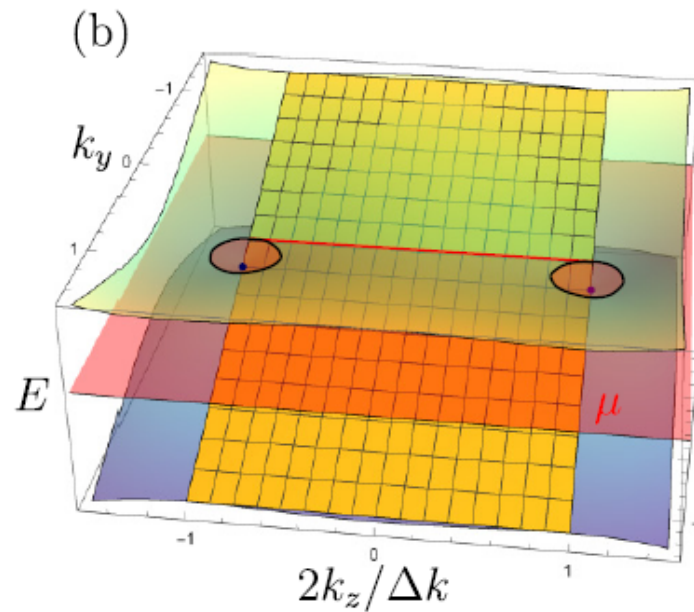
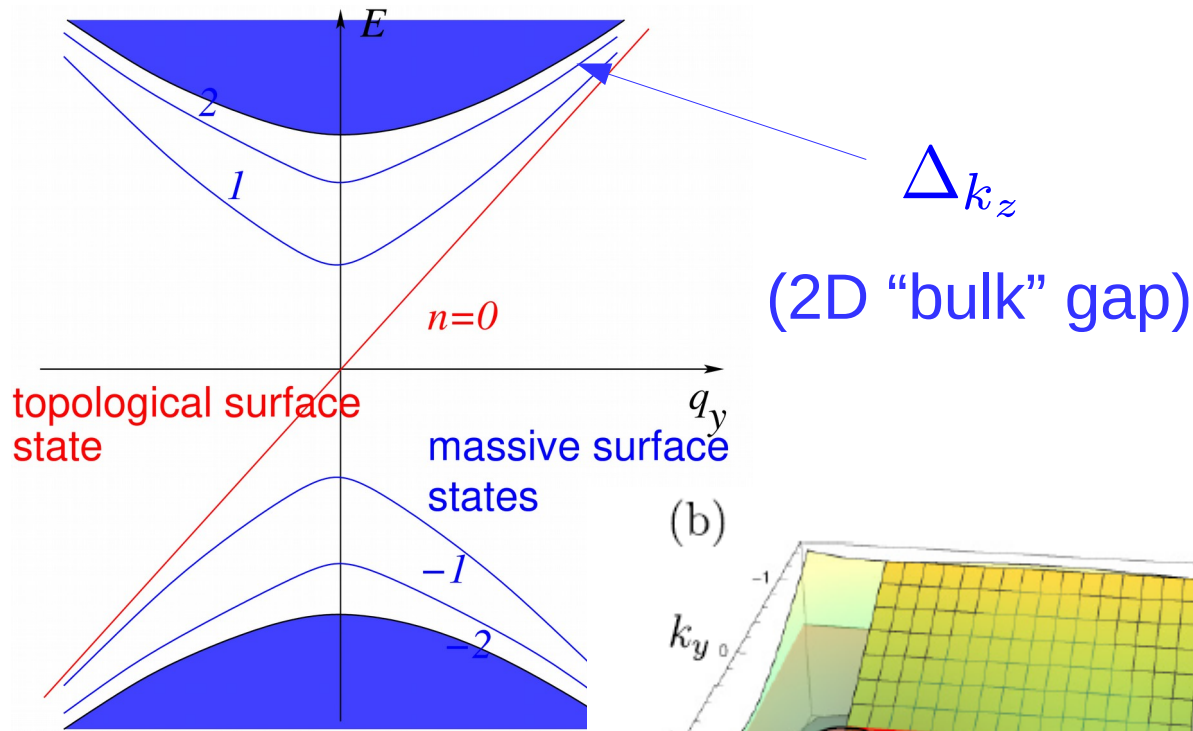
$$C_{\lambda}(k_z) = -\frac{1}{2} \lambda \operatorname{sgn}(\Delta_{k_z})$$



Fermi arc as a collection of 1D edge channels



Fermi arc as a collection of 1D edge channels

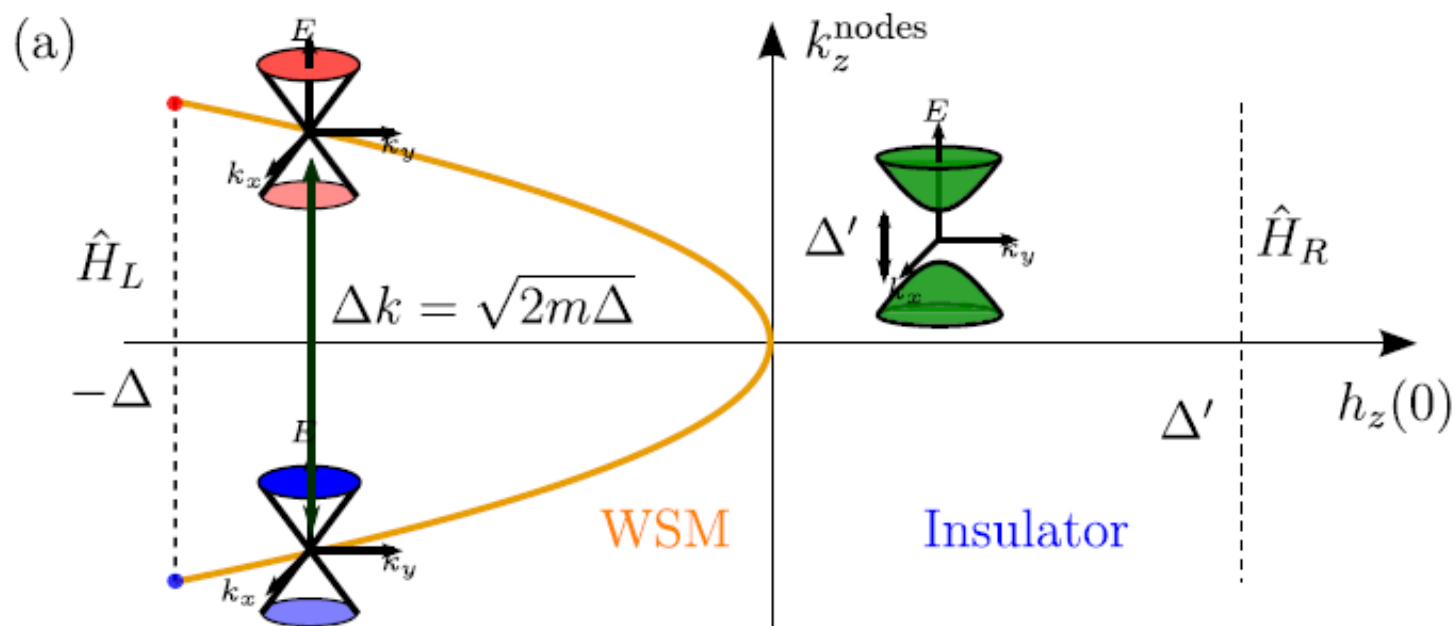


Fermi arc in a smooth interface \rightarrow TI

Effective interface model for Weyl node merging:

$$\Delta \rightarrow \Delta(\mathbf{x}) = \Delta - \Delta' \frac{x}{\ell}$$

$$H = \begin{pmatrix} \Delta(\mathbf{x}) - \frac{\hbar^2 k_z^2}{2m_0} & \hbar v(k_x - ik_y) \\ \hbar v(k_x + ik_y) & -\Delta(\mathbf{x}) + \frac{\hbar^2 k_z^2}{2m_0} \end{pmatrix}$$



Fermi arc in a smooth interface \rightarrow TI

Effective interface model for Weyl node merging:

$$\Delta \rightarrow \Delta(x) = \Delta - \Delta' \frac{x}{\ell}$$

change of “quantization axis” (unitary trafo)

$$\sigma_z \rightarrow -\sigma_y, \quad \sigma_y \rightarrow \sigma_z$$

$$H = \begin{pmatrix} \hbar v k_y & \sqrt{2} \hbar \frac{v}{\ell_S} a \\ \sqrt{2} \hbar \frac{v}{\ell_S} a^\dagger & \hbar v k_y \end{pmatrix}$$

ladder operators:

$$a = \frac{\ell_S}{\sqrt{2}} \left[k_x + i \frac{x - x_0}{\ell_S^2} \right] \quad \text{and} \quad a^\dagger = \frac{\ell_S}{\sqrt{2}} \left[k_x - i \frac{x - x_0}{\ell_S^2} \right]$$

$$\text{with } [a, a^\dagger] = 1$$

Tchoumakov, Civelli & MOG, PRB (2017)
Grushin et al., PRX (2016)

Fermi arc in a smooth interface \rightarrow TI

Effective interface model for Weyl node merging:

$$\Delta \rightarrow \Delta(x) = \Delta - \Delta' \frac{x}{\ell}$$

change of “quantization axis” (unitary trafo)

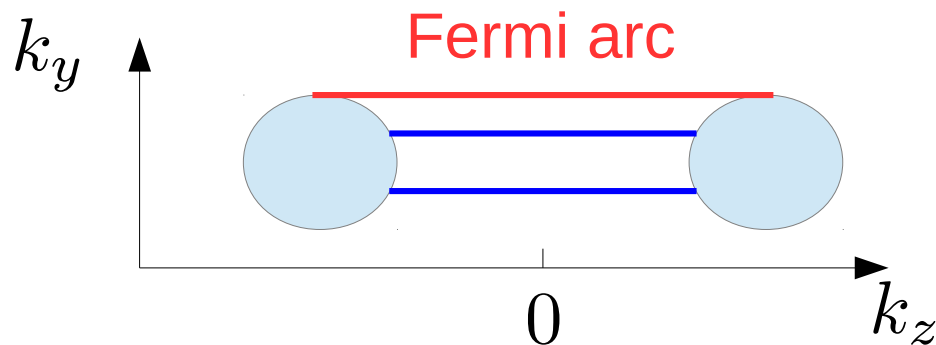
$$\sigma_z \rightarrow -\sigma_y, \quad \sigma_y \rightarrow \sigma_z$$

$$H = \begin{pmatrix} \hbar v k_y & \sqrt{2} \hbar \frac{v}{\ell_S} a \\ \sqrt{2} \hbar \frac{v}{\ell_S} a^\dagger & \hbar v k_y \end{pmatrix}$$

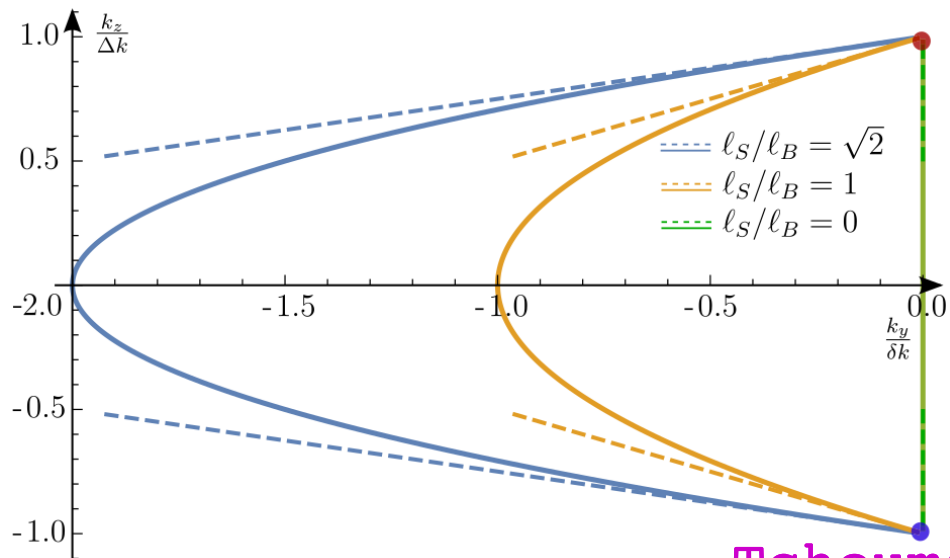
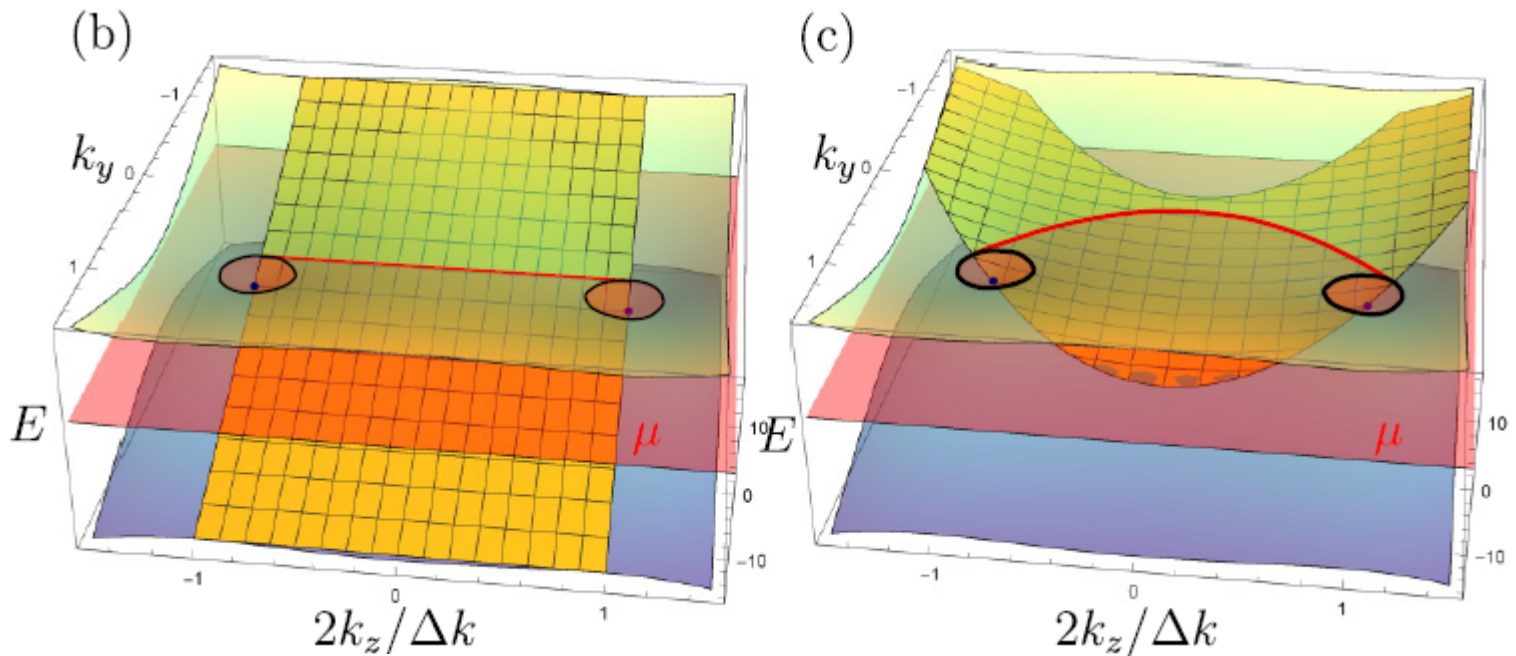
“Landau levels”:

$$E_{n=0}(k_y) = \hbar v k_y \quad \leftarrow \text{Fermi arc}$$

$$E_{\lambda, n \neq 0}(k_y) = \lambda \hbar v \sqrt{k_y^2 + 2n/\ell_S^2} \quad \leftarrow \text{massive VP states}$$



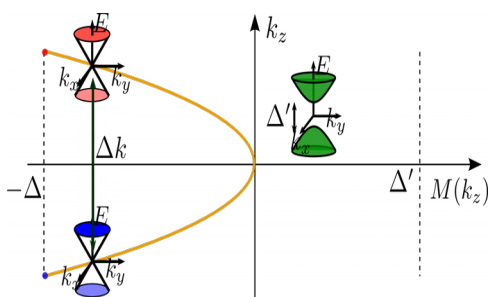
Dispersing Fermi arcs



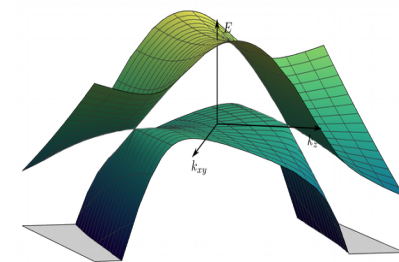
dispersion of Fermi arcs in k_z

→ magnetic field in interface
(conspires with confinement)

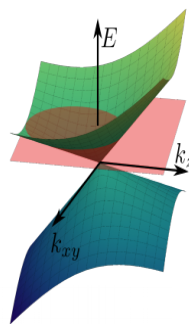
Surface states of tilted Weyl nodes



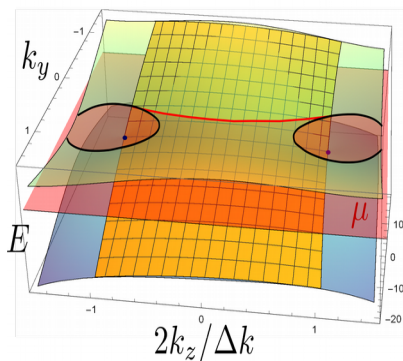
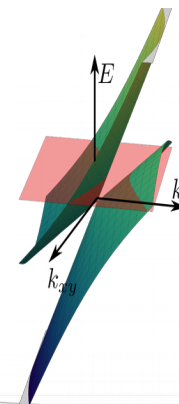
$$H = \underbrace{t_z(x) \left(\frac{k_z^2}{2m} - \Delta(x) \right)}_{\text{electric}} + \underbrace{\frac{v_F k_z}{\Delta k} (t_x k_x + t_y(x) k_y)}_{\text{magnetic}} + v_F (k_x \sigma_x + k_y \sigma_y) + \left[\frac{k_z^2}{2m} - \Delta(x) \right] \sigma_z$$



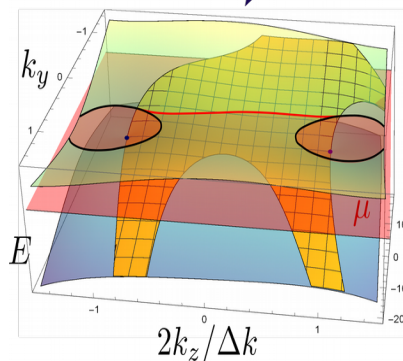
➤ Type-I Weyl semimetals



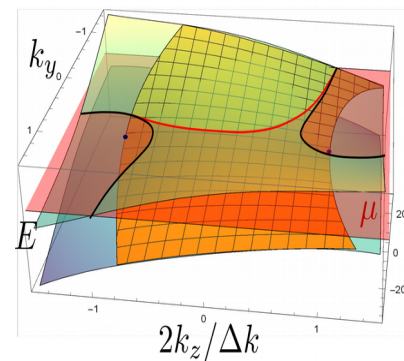
➤ Type-II Weyl semimetals



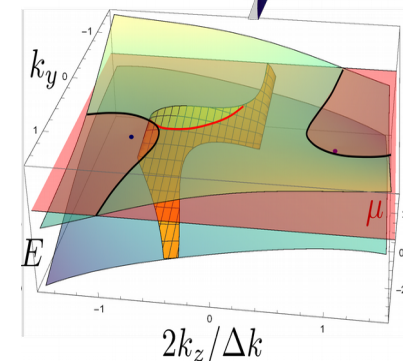
$\Delta' \gg \Delta$



$\Delta' \sim \Delta$

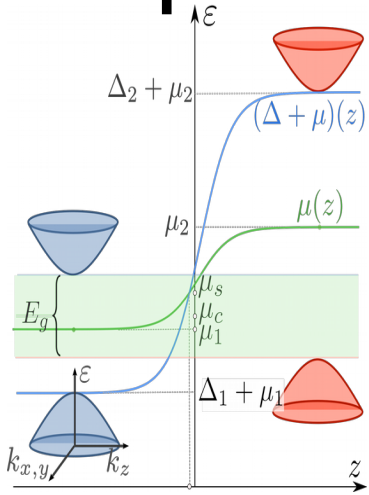


$\Delta' \gg \Delta$



$\Delta' \sim \Delta$

Special relativity in surface states

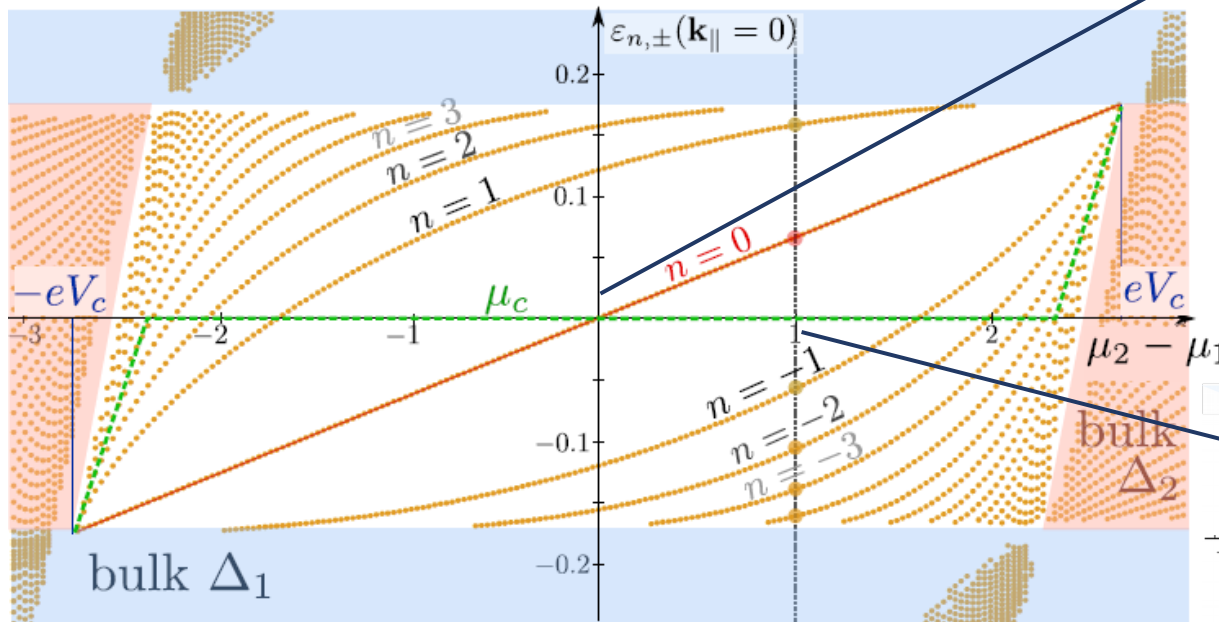
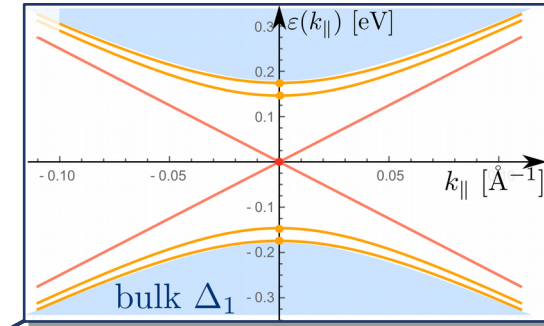


$$H = \mathbf{V}(\mathbf{z}) \cdot \mathbf{l} + v_F(k_x \mathbf{l} \otimes \tau_y + (k_y \sigma_x - k_x \sigma_y) \otimes \tau_x) + \Delta(\mathbf{z}) \mathbf{l} \otimes \tau_z$$

$$\text{Lorentz boost : } \beta = -\frac{\mu_2 - \mu_1}{\Delta_2 - \Delta_1}$$

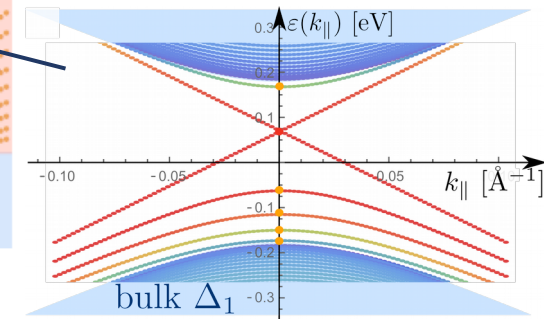
$$\text{Electric field: } \mathbf{E} \rightarrow \mathbf{E}' = 0$$

$$\text{Magnetic field: } \mathbf{B} \rightarrow \mathbf{B} \sqrt{1 - \beta^2}$$

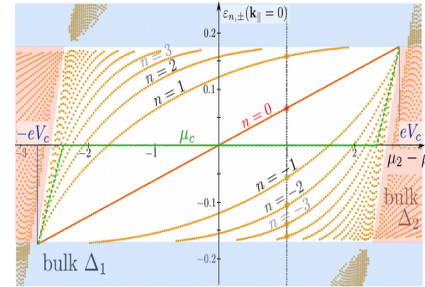


$$\Delta'_n \approx (1 - \beta^2)^{3/4} \Delta_n$$

$$\mu'_s = -\beta \Delta_1$$



Experimental evidence



Qualitative agreement

